

# TLE8209-2SA

SPI Programmable H-Bridge

Automotive Power



Never stop thinking

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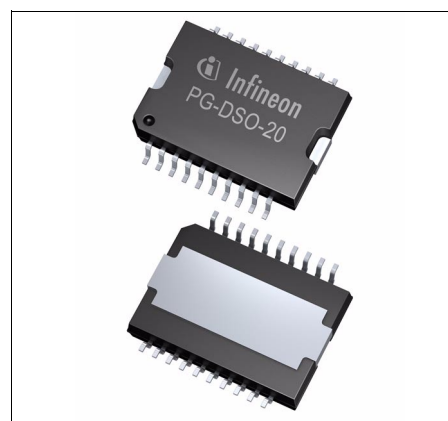
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## 1 Overview

### Features

- Programmable current limitation from 1.5 to 8.6 A typ.
- Full path  $R_{DSon}$  of 240 m $\Omega$  (typ. at  $T_j=25^{\circ}\text{C}$ )
- Operating battery supply voltage 4.5 V to 28 V
- Operating logic supply voltage 4.4 to 5.25 V
- Low standby current (8  $\mu\text{A}$  typ.)
- Logic inputs TTL/CMOS-compatible
- All I/O pins overvoltage tolerant up to 18 V
- Enable and disable input
- Short circuit and overtemperature protection
- $V_S$  undervoltage shutdown
- $V_{DD}$  over- and undervoltage monitoring
- Open load detection in off condition
- Temperature dependent current reduction
- Extensive diagnosis capabilities via SPI interface
- Status Flag for basic diagnosis without SPI
- Configurable as H-bridge or two independent half bridges
- Control of power stages by parallel inputs or via SPI
- Output switching frequency up to 11 kHz
- Slewrate programmable through SPI
- Excellent EMC performance
- AEC qualified
- Green product (RoHS compliant)



**PG-DSO-20-65**

### Functional Description

The TLE8209-2SA is a SPI programmable H-bridge, designed for the control of DC motors in safety critical automotive applications. It features four selectable current ranges, two selectable slew rate settings and extensive diagnosis via SPI. The device monitors the digital supply voltage  $V_{DD}$  and shuts down the output stages in case of  $V_{DD}$  over- or undervoltage, thus providing a safe switch off path in case of malfunction of the digital control circuitry. In order to reduce power dissipation in extreme thermal conditions the current limitation threshold is reduced linearly for junction temperatures over 165°C. A thermal warning bit is set in the SPI.

The two half bridges can also be used independently to drive two separate loads like solenoids or unidirectional DC motors.

| Type        | Package      | Body Width | Marking     |
|-------------|--------------|------------|-------------|
| TLE8209-2SA | PG-DSO-20-65 | 430 mil    | TLE8209-2SA |

## 2 Pin Configuration

### 2.1 Pin Assignment

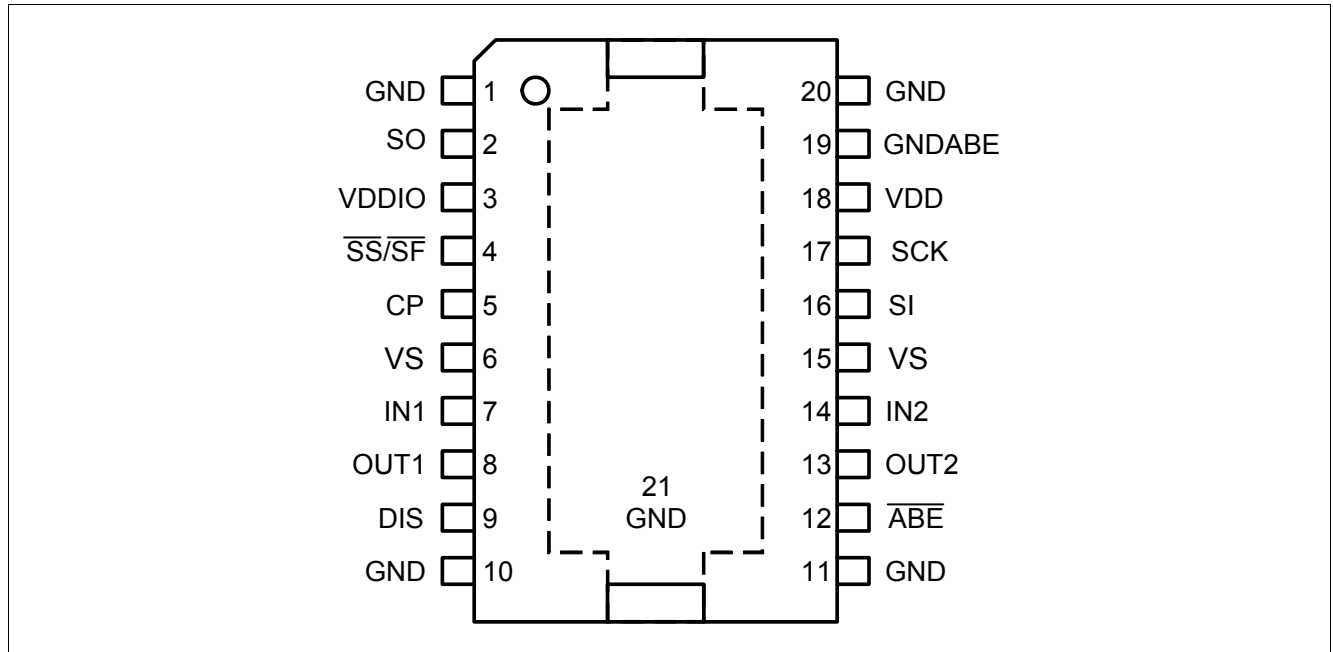


Figure 1 Pinout TLE8209-2SA

### 2.2 Pin Definitions and Functions

| Pin | Symbol | Function in SPI Mode                                       | Function in Status Flag Mode                               |
|-----|--------|------------------------------------------------------------|------------------------------------------------------------|
| 1   | GND    | Ground                                                     | Ground                                                     |
| 2   | SO     | SPI Serial Data Out                                        | no function - connect to GND                               |
| 3   | VDDIO  | Supply Voltage for Logic Output Buffer                     | Switches to SF-mode if connected to GND                    |
| 4   | SS/SF  | Slave Select (low active)                                  | Status Flag (low active)                                   |
| 5   | CP     | Pin for external Charge Pump Capacitor                     | Pin for external Charge Pump Capacitor                     |
| 6   | VS     | Battery Supply Voltage, has to be connected to pin 15      | Battery Supply Voltage, has to be connected to pin 15      |
| 7   | IN1    | Input 1                                                    | Input 1                                                    |
| 8   | OUT1   | Output 1                                                   | Output 1                                                   |
| 9   | DIS    | Disable                                                    | Disable                                                    |
| 10  | GND    | Ground                                                     | Ground                                                     |
| 11  | GND    | Ground                                                     | Ground                                                     |
| 12  | ABE    | Bidirectional Enable Pin                                   | Bidirectional Enable Pin                                   |
| 13  | OUT2   | Output 2                                                   | Output 2                                                   |
| 14  | IN2    | Input 2                                                    | Input 2                                                    |
| 15  | VS     | Input battery supply voltage, has to be connected to pin 6 | Input battery supply voltage, has to be connected to pin 6 |
| 16  | SI     | SPI Serial Data Input                                      | no function - connect to GND                               |

## Pin Configuration

| Pin | Symbol | Function in SPI Mode                 | Function in Status Flag Mode         |
|-----|--------|--------------------------------------|--------------------------------------|
| 17  | SCK    | SPI Clock                            | no function - connect to GND         |
| 18  | VDD    | $V_{DD}$ supply                      | $V_{DD}$ supply                      |
| 19  | GNDABE | Sense ground for $V_{DD}$ monitoring | Sense ground for $V_{DD}$ monitoring |
| 20  | GND    | Ground                               | Ground                               |
| 21  | GND    | Heatslug - connect to GND            | Heatslug - connect to GND            |

## 2.3 Terms

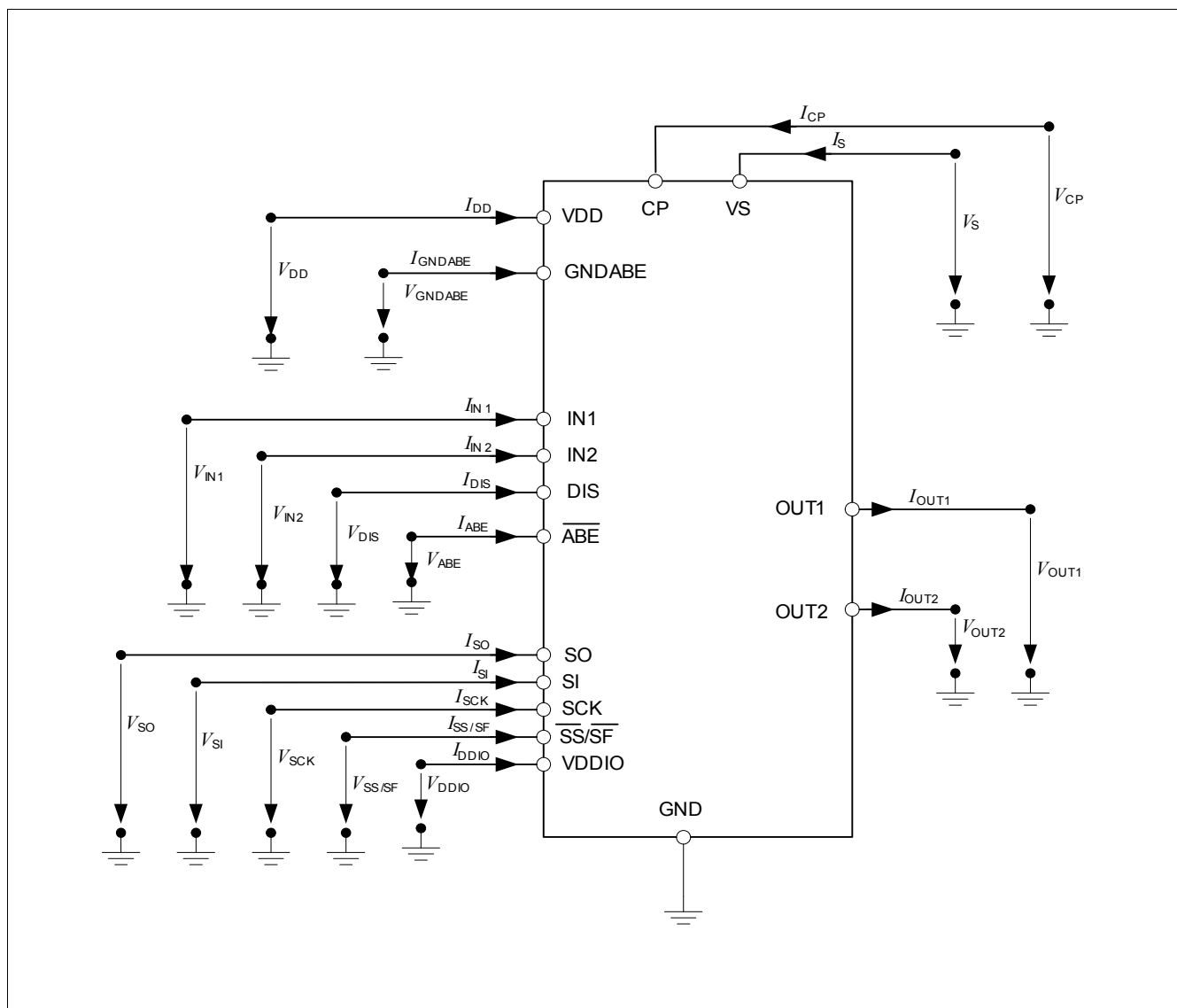


Figure 2 Terms TLE8209-2SA

### 3 Block Diagram

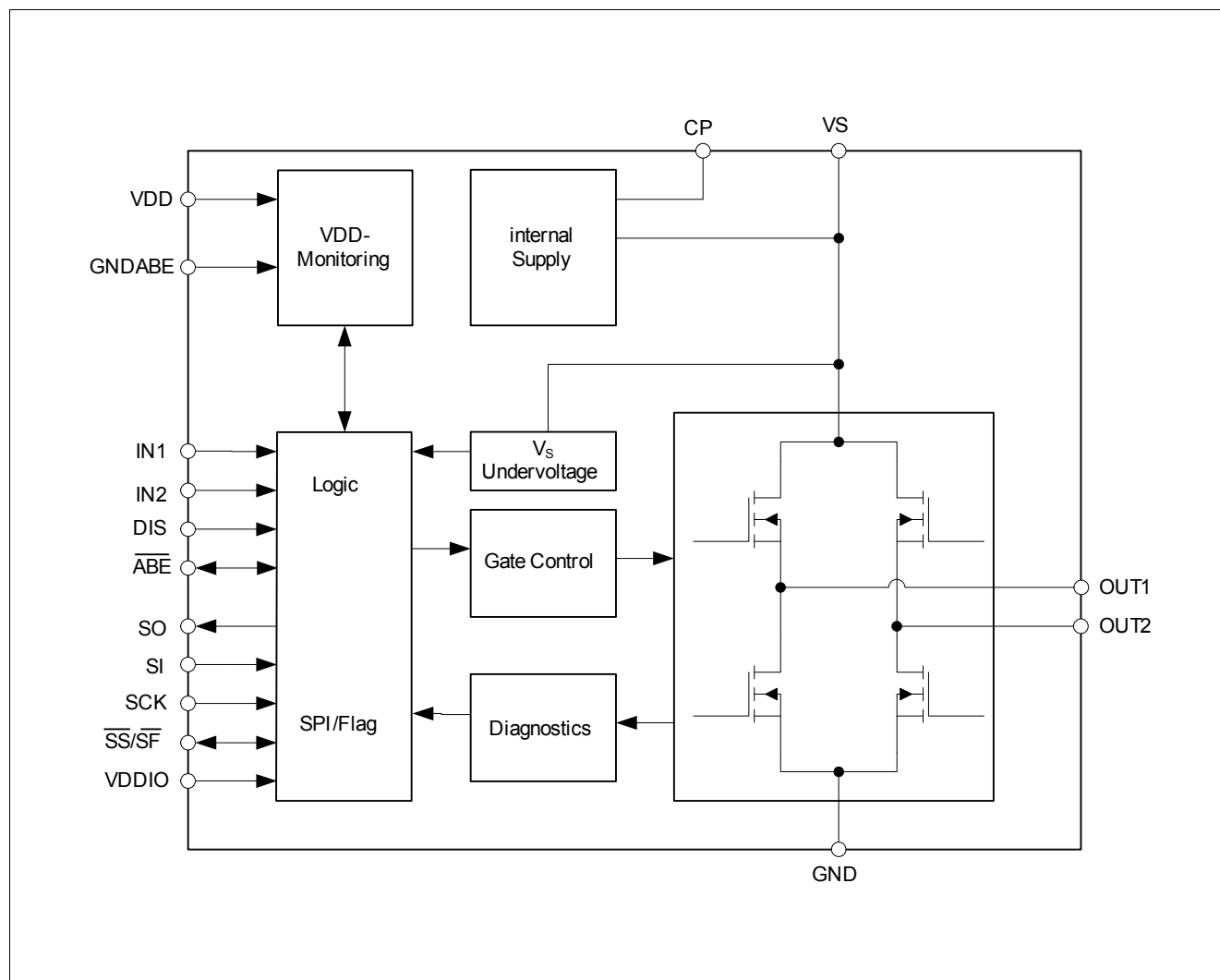


Figure 3 Block Diagram TLE8209-2SA

## 4 General Product Characteristics

### 4.1 Absolute Maximum Ratings

#### Absolute Maximum Ratings <sup>1)</sup>

$T_j = -40 \text{ °C to } 150 \text{ °C}$ ; all voltages with respect to ground, positive current flowing into pin  
(unless otherwise specified)

| Pos.   | Parameter                                                      | Symbol       | Limit Values    |                  | Unit | Test Conditions / Comment                                                                         |
|--------|----------------------------------------------------------------|--------------|-----------------|------------------|------|---------------------------------------------------------------------------------------------------|
|        |                                                                |              | Min.            | Max.             |      |                                                                                                   |
| 4.1.1  | Junction temperature                                           | $T_j$        | -40<br>150      | 150<br>175       | °C   | –<br>100h cumulative                                                                              |
| 4.1.2  | Storage temperature                                            | $T_s$        | -55             | 150              | °C   | –                                                                                                 |
| 4.1.3  | Ambient temperature                                            | $T_a$        | -40             | 125              | °C   | –                                                                                                 |
| 4.1.4  | Battery supply voltage                                         | $V_S$        | -0.5            | 40               | V    | Static destruction proof                                                                          |
|        |                                                                |              | -2              | 40               | V    | Dynamic destruction proof<br>$t < 0.5 \text{ s}$ (single pulse,<br>$T_{jstart} < 85 \text{ °C}$ ) |
| 4.1.5  | Logic supply voltage                                           | $V_{DD}$     | -0.5            | 18               | V    | –                                                                                                 |
| 4.1.6  | Supply for logic out                                           | $V_{DDIO}$   | -0.5            | 18               | V    | –                                                                                                 |
| 4.1.7  | Voltage at logic pins<br>ABE, IN1, IN2, DIS, SCK,<br>SS/SF, SI | $V_{IN}$     | -0.5            | 18               | V    | –                                                                                                 |
| 4.1.8  | Voltage at SO                                                  | $V_{SO}$     | -0.5            | $V_{DDIO} + 0.3$ | V    | –                                                                                                 |
| 4.1.9  | Voltage at CP                                                  | $V_{CP}$     | $V_S - 0.3$     | $V_S + 5.0$      | V    | $0V < V_S < 40V$                                                                                  |
| 4.1.10 | Voltage at GNDABE                                              | $V_{GNDABE}$ | $V_{GND} - 0.3$ | $V_{GND} + 0.3$  | V    |                                                                                                   |

#### ESD Susceptibility

|        |                        |           |      |     |    |                                        |
|--------|------------------------|-----------|------|-----|----|----------------------------------------|
| 4.1.11 | ESD Resistivity to GND | $V_{ESD}$ | -2   | 2   | kV | HBM <sup>2)</sup>                      |
| 4.1.12 |                        |           | -8   | 8   | kV | HBM <sup>2)</sup> , Pins OUT1 and OUT2 |
| 4.1.13 |                        |           | -500 | 500 | V  | CDM <sup>3)</sup>                      |
| 4.1.14 |                        |           | -750 | 750 | V  | CDM <sup>3)</sup> , Pins 1, 10, 11, 20 |

1) Not subject to production test, specified by design.

2) ESD susceptibility HBM according to EIA/JESD22-A114-B (1.5kΩ, 100pF)

3) ESD susceptibility, Charged Device Model "CDM" EIA/JESD22-C101

*Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

*Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.*

## 4.2 Operating Range

| Pos.  | Parameter                  | Symbol     | Limit Values |      | Unit | Remark |
|-------|----------------------------|------------|--------------|------|------|--------|
|       |                            |            | Min.         | Max. |      |        |
| 4.2.1 | $V_S$ supply voltage range | $V_S$      | 4.5          | 28   | V    | –      |
| 4.2.2 | $V_{DD}$ supply voltage    | $V_{DD}$   | 4.4          | 5.25 | V    | –      |
| 4.2.3 | $V_{DDIO}$ supply voltage  | $V_{DDIO}$ | 0            | 5.5  | V    | –      |
| 4.2.4 | PWM frequency              | $f$        | –            | 11   | kHz  | –      |
| 4.2.5 | Junction temperature       | $T_J$      | -40          | 150  | °C   | –      |

Note: Within the operating range the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the related electrical characteristics table.

## 4.3 Thermal Resistance

| Pos.  | Parameter                         | Symbol     | Limit Values |      |      | Unit | Remark        |
|-------|-----------------------------------|------------|--------------|------|------|------|---------------|
|       |                                   |            | Min.         | Typ. | Max. |      |               |
| 4.3.6 | Junction to Case <sup>1)</sup>    | $R_{thJC}$ | –            | –    | 1.6  | K/W  | –             |
| 4.3.7 | Junction to Ambient <sup>1)</sup> | $R_{thJA}$ | –            | 17   | –    | K/W  | <sup>2)</sup> |

1) Not subject to production test, specified by design.

2) Simulation according to Jedec JESD51-2,-5,-7; natural convection; FR4 2s2p board 76.2 x 114.3 x 1.5 mm (2 x 70µm Cu, 2 x 35µm Cu)

## 5 Power Supply

### 5.1 Basic Supply Characteristics

The TLE8209-2SA has three different supply pins: VDD, VS and VDDIO. VDD is used to supply the internal logic circuitry. VS connects to battery voltage and supplies the output stages. The voltage at pin VDDIO defines the high level output voltage at the pin SO of the SPI interface. VDDIO is also used as a mode select pin. If VDDIO is connected to ground, the device is set to status flag mode (SPI inactive).

On power up the device will enter a functional state when  $V_{DD}$  rises above the functional reset threshold  $V_{DD\_RES}$ . In this state all output stages are inactive and internal registers are cleared. When  $V_{DD}$  rises further above the power on reset threshold  $V_{DD\_POR}$  the device starts operation with a delay time of  $t_{POR}$ .

### 5.2 VDD Monitoring

The logic supply voltage level at the pin VDD is monitored. If the voltage at pin  $V_{DD}$  is out of the permissible range of  $V_{DD\_L} \dots V_{DD\_H}$  the power stages of TLE8209-2SA are switched off and pin  $\overline{ABE}$  is pulled to ground. To suppress glitches in the  $V_{DD}$  monitoring, a glitch filter is implemented.  $V_{DD}$  is measured with reference to pin GNDABE. The state of VDD monitoring is stored in STATCON\_REG and can be read out via SPI.

The output stages can also be turned off by pulling the  $\overline{ABE}$  pin to ground externally.

In case of VDD failure, the output stages are switched off, even if the pin  $\overline{ABE}$  should be connected to a high level signal because of external short circuit to VDD or battery voltage (up to 18V). OUT1 and OUT2 cannot be switched on in over- or undervoltage condition, switching off is always possible. A power on reset ( $V_{DD} < V_{DD\_POR}$ ) switches off all stages without delay.

Control of VDD-monitoring is possible in SPI mode only. Detailed information (differentiation of over and undervoltage detection) is only possible by SPI interface.

#### Behavior of VDD monitoring in SF mode:

- monitoring is present with the specified values for over- and undervoltage
- any test of over- and undervoltage threshold is not possible
- the latch for overvoltage is disabled

#### VDD Undervoltage

If the VDD voltage is lower than the supply voltage supervisory lower threshold ( $V_{DD\_THL}$ ), output stages are shut off after a filtering time ( $t_{FIL\_OFF}$ ) and the bi-directional pin  $\overline{ABE}$  is pulled low. At the transition from undervoltage to normal voltage the signal at pin  $\overline{ABE}$  goes high and the output stages will return to normal operation after a filtering time ( $t_{FIL\_ON}$ ) has expired. For output control via SPI the bits MUX and SINx in the config register have to be re-programmed. New failures are not stored to diagnostic registers during undervoltage, register content remains valid, writing new information to configuration registers is possible as far as they are not reset by  $\overline{ABE}$ . If VDD falls below the power-on-reset supply voltage ( $V_{DD\_POR}$ ) all stages are shut off and  $\overline{ABE}$  is switched active low. When VDD is rising above the power-on-reset supply voltage threshold ( $V_{DD\_POR}$ ) a power-on-reset is generated ( $t_{POR}$ ), setting all registers to its default state.

#### VDD Overvoltage

If the VDD voltage is higher than the supply voltage supervisory upper threshold ( $V_{DD\_THH}$ ), all output stages are shut off after a filtering time ( $t_{FIL\_OFF}$ ) and the bi-directional pin  $\overline{ABE}$  is pulled low. The behavior of the  $\overline{ABE}$  level and output stages on the return of VDD from overvoltage to the correct range is configured in STATCON\_REG, bit CONFIG0

CONFIG0='1':  $\overline{ABE}$  is latched and outputs remain off after overvoltage. Return to normal operation is only possible with power-on reset or by changing this bit via SPI.

CONFIG0='0':  $\overline{\text{ABE}}$  is inactive after VDD returned to normal operating voltage and filtering time has expired.

At the transition from overvoltage to normal condition, the output stages will return to normal operation. For output control via SPI the bits MUX and SINx in the config register have to be re-programmed. New failures are not stored to diagnostic registers during overvoltage, register content remains valid, writing new information to configure registers is possible as far as they are not reset by  $\overline{\text{ABE}}$ .

### VDD Monitoring Test Mode

Testing of VDD monitoring is possible in SPI mode only. The latch function for over voltage at VDD has to be switched of (CONFIG0=0 in STATCON\_REG)

#### Testing upper threshold:

By writing 00xxxxxb into STATCON\_REG, the overvoltage threshold is reduced to VDD\_TEST\_H. STATCON\_REG bit 2 and 0 have to be LOW then. After writing 1xxxxxb to STATCON\_REG, bit 2 and 0 in STATCON\_REG must be HIGH again

#### Testing lower threshold:

By writing 01xxxxxb into STATCON\_REG, the undervoltage threshold is increased to VDD\_TEST\_L. STATCON\_REG bit 2 and 1 have to be LOW then. After writing 1xxxxxb to STATCON\_REG, bit 2 and 1 in STATCON\_REG must be HIGH again.

## 5.3 VDDIO - Digital Output Supply and Diagnostic Mode Selection

The voltage at  $V_{\text{DDIO}}$  is used to supply the output buffer at the SO pin (serial output of SPI-interface). The VDDIO pin is also used to select SPI- or in status flag (SF) diagnostic mode. As soon as  $V_{\text{DDIO}}$  is lower than  $V_{\text{DDIO\_L}}$ , the device is put into status flag mode.

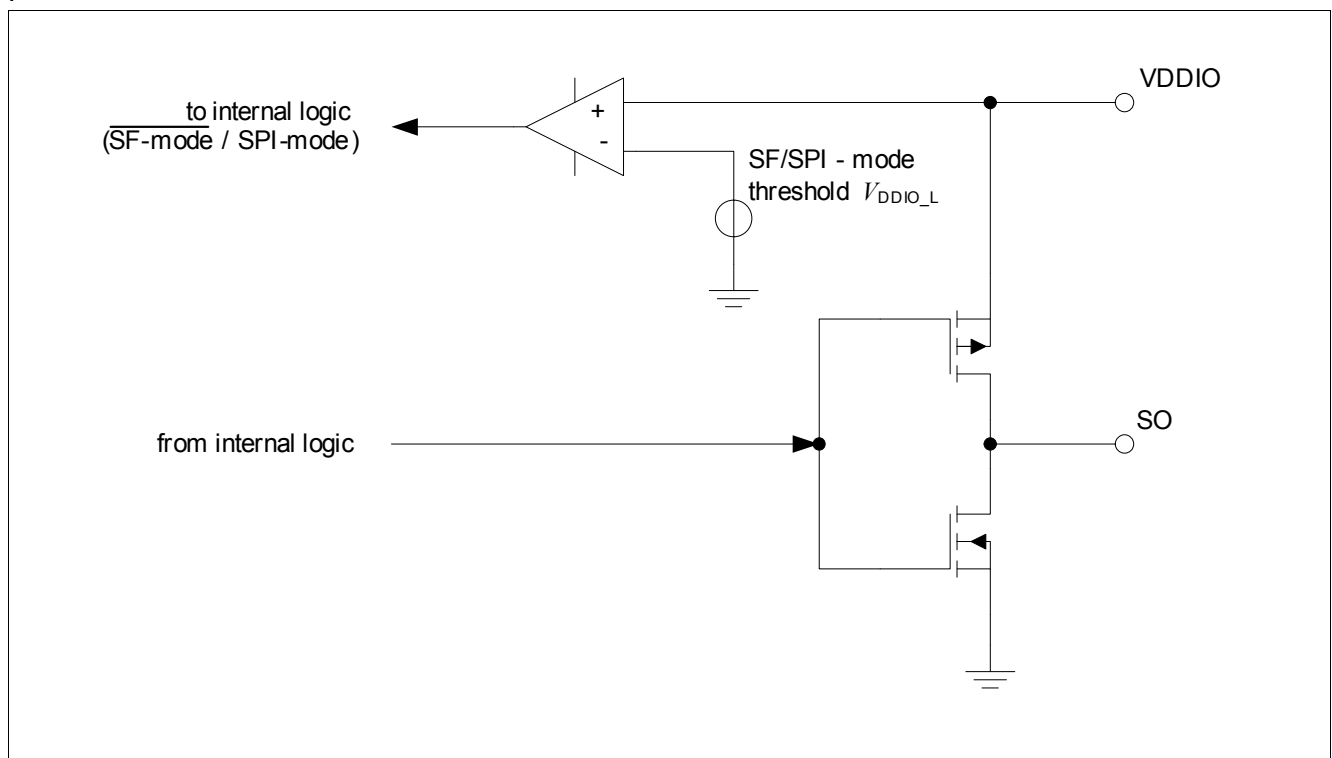


Figure 4  $V_{\text{DDIO}}$  and SO-Pin

## 5.4 Electrical Characteristics Power Supply and $V_{DD}$ -Monitoring

### Electrical Characteristics: Power Supply and $V_{DD}$ -Monitoring

$V_S = 5\text{ V to } 28\text{ V}$ ;  $V_{DD} = 5.0\text{ V}$ ,  $T_j = -40\text{ }^\circ\text{C to } 150\text{ }^\circ\text{C}$ , all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

| Pos.                        | Parameter                                  | Symbol            | Limit Values |      |      | Unit | Test Conditions                                                                                       |
|-----------------------------|--------------------------------------------|-------------------|--------------|------|------|------|-------------------------------------------------------------------------------------------------------|
|                             |                                            |                   | Min.         | Typ. | Max. |      |                                                                                                       |
| Supply                      |                                            |                   |              |      |      |      |                                                                                                       |
| 5.4.1                       | Supply Current                             | $I_{VS}$          | –            | 8    | 20   | μA   | $I_{OUT} = 0\text{ A}$ , $V_{DD} = 0\text{ V}$ ,<br>$V_S < 18\text{ V}$ , $T_j < 125^{\circ}\text{C}$ |
|                             |                                            |                   | –            | 2.1  | 4    | mA   | bridge disabled,<br>$I_{OUT} = 0\text{ A}$ ,<br>$5\text{ V} < V_S < 18\text{ V}$                      |
|                             |                                            |                   | –            | 2.5  | 5    | mA   | $f = 2\text{ kHz}$ , $I_{OUT} = 0\text{ A}$ ,<br>$5\text{ V} < V_S < 18\text{ V}$                     |
|                             |                                            |                   | –            | 4    | 9    | mA   | $f = 10\text{ kHz}$ , $I_{OUT} = 0\text{ A}$ ,<br>$5\text{ V} < V_S < 18\text{ V}$                    |
|                             |                                            |                   | –            | 4.8  | 13   | mA   | $f = 10\text{ kHz}$ , $I_{OUT} = 0\text{ A}$ ,<br>$5\text{ V} < V_S < 28\text{ V}$                    |
| 5.4.2                       | Functional Reset Threshold                 | $V_{DD\_RES}$     | –            | 1.4  | 2.5  | V    | –                                                                                                     |
| 5.4.3                       | Power On Reset Threshold                   | $V_{DD\_POR}$     | 3.5          | 3.75 | 4.0  | V    | –                                                                                                     |
| 5.4.4                       | Power On Reset Delay Time                  | $t_{POR}$         | –            | 0.22 | 0.5  | ms   | $V_{DD} = \text{on} \rightarrow$ output stage active, no load                                         |
| 5.4.5                       | VDD Input current                          | $I_{DD}$          | –            | 7    | 9    | mA   | $4.5\text{ V} < V_{DD} < 5.5\text{ V}$                                                                |
| 5.4.6                       | VDDIO Input current                        | $I_{DDIO}$        | –            | 30   | 100  | μA   | SPI-mode<br>no load at SO<br>no SPI communication                                                     |
| 5.4.7                       | SF-mode Threshold                          | $V_{DDIO\_L}$     | –            | –    | 1.0  | V    | –                                                                                                     |
| 5.4.8                       | SPI-mode Threshold                         | $V_{DDIO\_H}$     | 2.0          | –    | –    | V    | –                                                                                                     |
| 5.4.9                       | Mode selection hysteresis                  | $V_{DDIO\_HYS}$   | 0.2          | 0.5  | 1.0  | V    | –                                                                                                     |
| V <sub>DD</sub> -Monitoring |                                            |                   |              |      |      |      |                                                                                                       |
| 5.4.10                      | Overvoltage threshold                      | $V_{DD\_THH}$     | 5.25         | 5.4  | 5.5  | V    | Voltage referred to GNDABE                                                                            |
| 5.4.11                      | Undervoltage threshold                     | $V_{DD\_THL}$     | 4.2          | 4.3  | 4.4  | V    |                                                                                                       |
| 5.4.12                      | Test mode reduced Overvoltage threshold    | $V_{DD\_TEST\_H}$ | 4.2          | 4.3  | 4.4  | V    |                                                                                                       |
| 5.4.13                      | Test mode increased Undervoltage threshold | $V_{DD\_TEST\_L}$ | 5.25         | 5.4  | 5.5  | V    |                                                                                                       |
| 5.4.14                      | Filter time for glitch suppression         | $t_{FIL}$         | 60           | 100  | 135  | μs   | –                                                                                                     |
| 5.4.15                      | Maximum Slew Rate on VDD <sup>1)</sup>     | $V_{DD\_slew}$    | –            | –    | 0.5  | V/μs | –                                                                                                     |

1) Not subject to production test; specified by design

## 6 Logic Inputs and Outputs

The threshold specifications for the logic inputs are compatible to both 5 and 3.3 V standard CMOS microcontroller ports. All inputs (except  $\overline{\text{ABE}}$ ) feature internal pull-up current sources. The logic output SO is supplied by  $V_{\text{DDIO}}$ .  $V_{\text{DDIO}}$  can be supplied with either 5 or 3.3 V, so the output thresholds of SO can be configured to the required I/O voltage.

### Electrical Characteristics: Control Inputs

$V_{\text{S}} = 5 \text{ V to } 28 \text{ V}$ ;  $V_{\text{DD}} = 5.0 \text{ V}$ ;  $T_{\text{J}} = -40 \text{ }^{\circ}\text{C to } 150 \text{ }^{\circ}\text{C}$ , all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

| Pos.     | Parameter                         | Symbol                 | Limit Values              |      |                           | Unit | Test Conditions                                                                       |
|----------|-----------------------------------|------------------------|---------------------------|------|---------------------------|------|---------------------------------------------------------------------------------------|
|          |                                   |                        | Min.                      | Typ. | Max.                      |      |                                                                                       |
| IN1, IN2 |                                   |                        |                           |      |                           |      |                                                                                       |
| 6.0.1    | Low level                         | $V_{\text{INx\_L}}$    | -0.3                      | –    | 1.0                       | V    | –                                                                                     |
| 6.0.2    | High level                        | $V_{\text{INx\_H}}$    | 2.0                       | –    | $V_{\text{DD}}+0.3$       | V    | –                                                                                     |
| 6.0.3    | Hysteresis                        | $V_{\text{INx\_HYS}}$  | 0.2                       | –    | 1.0                       | V    | –                                                                                     |
| 6.0.4    | Input Current (Pull Up)           | $I_{\text{INx}}$       | -30                       | -20  | -10                       | μA   | $0\text{ V} < V_{\text{INx}} < 2.1\text{ V}$                                          |
| 6.0.5    |                                   |                        | 0                         | 2    | 5                         | μA   | $V_{\text{INx}} > 3.0\text{ V}$                                                       |
| 6.0.6    | Input Capacity <sup>1)</sup>      | $C_{\text{INx}}$       | –                         | –    | 20                        | pF   | 2)                                                                                    |
| DIS      |                                   |                        |                           |      |                           |      |                                                                                       |
| 6.0.7    | Low level                         | $V_{\text{DIS\_L}}$    | -0.3                      | –    | 1.0                       | V    | –                                                                                     |
| 6.0.8    | High level                        | $V_{\text{DIS\_H}}$    | 2.0                       | –    | $V_{\text{DD}}+0.3$       | V    | –                                                                                     |
| 6.0.9    | Hysteresis                        | $V_{\text{DIS\_HYS}}$  | 0.2                       | –    | 1.0                       | V    | –                                                                                     |
| 6.0.10   | Input Current (Pull Up)           | $I_{\text{DIS}}$       | -200                      | -125 | -50                       | μA   | $0\text{ V} < V_{\text{DIS}} < 2.1\text{ V}$                                          |
| 6.0.11   |                                   |                        | 0                         | 2    | 5                         | μA   | $V_{\text{DIS}} > 3.0\text{ V}$                                                       |
| 6.0.12   | Input Capacity <sup>1)</sup>      | $C_{\text{DIS}}$       | –                         | –    | 20                        | pF   | 2)                                                                                    |
| 6.0.13   | Minimum Pulse Width <sup>1)</sup> | $t_{\text{DIS}}$       | 0.4                       | 0.8  | 1.5                       | μs   | –                                                                                     |
| ABE      |                                   |                        |                           |      |                           |      |                                                                                       |
| 6.0.14   | Output low-level voltage          | $V_{\text{ABE\_OUTL}}$ | –                         | –    | 1.2                       | V    | $V_{\text{DD\_THH}} < V_{\text{DD}} < 18\text{ V}$<br>$I_{\text{ABE}} < 5\text{ mA}$  |
| 6.0.15   |                                   |                        | –                         | –    | 1.0                       | V    | $2.5\text{ V} < V_{\text{DD}} < V_{\text{DD\_THL}}$<br>$I_{\text{ABE}} < 1\text{ mA}$ |
| 6.0.16   | Input threshold high              | $V_{\text{ABE\_INH}}$  | $0.7 \cdot V_{\text{DD}}$ | –    | –                         | V    | –                                                                                     |
| 6.0.17   | Input threshold low               | $V_{\text{ABE\_INL}}$  | –                         | –    | $0.3 \cdot V_{\text{DD}}$ | V    | –                                                                                     |
| 6.0.18   | Hysteresis                        | $V_{\text{ABE\_INHY}}$ | 0.2                       | –    | 1.0                       | V    | –                                                                                     |
| 6.0.19   | Minimum pulse width <sup>1)</sup> | $t_{\text{ABE}}$       | 0.4                       | 0.8  | 1.5                       | μs   | –                                                                                     |
| 6.0.20   | ABE Input current (Pull Down)     | $-I_{\text{ABE\_L}}$   | 20                        | 40   | 120                       | μA   | $1.5\text{ V} < V_{\text{ABE}} < 18\text{ V}$                                         |
| 6.0.21   |                                   |                        | 0                         | –    | 60                        | μA   | $0\text{ V} < V_{\text{ABE}} < 1.5\text{ V}$                                          |
| SI       |                                   |                        |                           |      |                           |      |                                                                                       |
| 6.0.22   | Low level                         | $V_{\text{SI\_L}}$     | -0.3                      | –    | 1.0                       | V    | –                                                                                     |
| 6.0.23   | High level                        | $V_{\text{SI\_H}}$     | 2.0                       | –    | $V_{\text{DD}}+0.3$       | V    | –                                                                                     |
| 6.0.24   | Hysteresis                        | $V_{\text{SI\_HYS}}$   | 0.2                       | –    | 1.0                       | V    | –                                                                                     |
| 6.0.25   | Input Current (Pull Up)           | $I_{\text{SI}}$        | -30                       | -20  | -10                       | μA   | $0\text{ V} < V_{\text{SI}} < 2.1\text{ V}$                                           |
| 6.0.26   | Input Capacity <sup>1)</sup>      | $C_{\text{SI}}$        |                           |      | 14                        | pF   | 2)                                                                                    |

## Logic Inputs and Outputs

**Electrical Characteristics: Control Inputs (cont'd)**

$V_S = 5\text{ V to } 28\text{ V}$ ;  $V_{DD} = 5.0\text{ V}$ ;  $T_j = -40\text{ }^\circ\text{C to } 150\text{ }^\circ\text{C}$ , all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

| Pos.   | Parameter                             | Symbol                | Limit Values           |      |                     | Unit | Test Conditions                                              |
|--------|---------------------------------------|-----------------------|------------------------|------|---------------------|------|--------------------------------------------------------------|
|        |                                       |                       | Min.                   | Typ. | Max.                |      |                                                              |
| SCK    |                                       |                       |                        |      |                     |      |                                                              |
| 6.0.27 | Low level                             | $V_{\text{SCK\_L}}$   | -0.3                   | –    | 1.0                 | V    | –                                                            |
| 6.0.28 | High level                            | $V_{\text{SCK\_H}}$   | 2.0                    | –    | $V_{\text{DD}}+0.3$ | V    | –                                                            |
| 6.0.29 | Hysteresis                            | $V_{\text{SCK\_HYS}}$ | 0.2                    | –    | 1.0                 | V    | –                                                            |
| 6.0.30 | Input Current (Pull Up)               | $I_{\text{SCK}}$      | -30                    | -20  | -10                 | μA   | 0 V < $V_{\text{SCK}}$ < 2.1 V                               |
| 6.0.31 | Input Capacity <sup>1)</sup>          | $C_{\text{SCK}}$      | –                      | –    | 14                  | pF   | <sup>2)</sup>                                                |
| SS/SF  |                                       |                       |                        |      |                     |      |                                                              |
| 6.0.32 | Low level                             | $V_{\text{SS\_L}}$    | -0.3                   | –    | 1.0                 | V    | –                                                            |
| 6.0.33 | High level                            | $V_{\text{SS\_H}}$    | 2.0                    | –    | $V_{\text{DD}}+0.3$ | V    | –                                                            |
| 6.0.34 | Hysteresis                            | $V_{\text{SS\_HYS}}$  | 0.2                    | –    | 1.0                 | V    | –                                                            |
| 6.0.35 | Input Current in SPI mode (Pull Up)   | $I_{\text{SS}}$       | -30                    | -20  | -10                 | μA   | 0 V < $V_{\text{SS}}$ < 2.1 V                                |
| 6.0.36 |                                       |                       | -30                    | –    | 5                   | μA   | 2.1 V < $V_{\text{SS}}$ < 3.0 V                              |
| 6.0.37 |                                       |                       | 0                      | 2    | 5                   | μA   | $V_{\text{SS}}$ > 3.0 V                                      |
| 6.0.38 | Input Current in SF mode (Open Drain) | $I_{\text{SF}}$       | 0                      | 2    | 5                   | μA   | $V_{\text{SF}}$ = 5.0 V, SF inactive                         |
| 6.0.39 |                                       |                       | 300                    | –    | –                   | μA   | $V_{\text{SF}}$ = 1.0 V, SF active                           |
| 6.0.40 | Input Capacity <sup>1)</sup>          | $C_{\text{SS}}$       | –                      | –    | 15                  | pF   | <sup>2)</sup>                                                |
| SO     |                                       |                       |                        |      |                     |      |                                                              |
| 6.0.41 | Low level                             | $V_{\text{SO\_L}}$    | 0.0                    | –    | 0.4                 | V    | $I_{\text{SO}}$ = 2 mA                                       |
| 6.0.42 | High level                            | $V_{\text{SO\_H}}$    | $V_{\text{DDIO}}-0.75$ | –    | $V_{\text{DDIO}}$   | V    | $I_{\text{SO}}$ = -2 mA<br>2.9 V < $V_{\text{DDIO}}$ < 5.5 V |
| 6.0.43 | Output capacitance <sup>1)</sup>      | $C_{\text{SO}}$       | –                      | –    | 19                  | pF   | In tristate <sup>2)</sup>                                    |
| 6.0.44 | Leakage current                       | $I_{\text{SO}}$       | -2                     | –    | 2                   | μA   | In tristate<br>0 < $V_{\text{SO}}$ < $V_{\text{DDIO}}$       |

1) Not subject to production test; specified by design

2)  $V_{bias} = 2\text{ V}$ ;  $V_{test} = 20\text{ mVpp}$ ;  $f = 1\text{ MHz}$

## 7 Power Stages

The TLE8209-2SA contains four n-channel power-DMOS transistors that can be used in an H-bridge or in dual half bridge configuration.

Integrated circuits protect the outputs against overcurrent and over-temperature, in case of short-circuit to ground, to the supply voltage or across the load. Positive and negative voltage spikes, which occur when switching inductive loads, are limited by integrated freewheeling diodes (body diodes of power-DMOS).

### 7.1 Parallel or SPI Control

By default the setting of the power switches is controlled by the Inputs IN1, IN2 (parallel control). The outputs OUT1 and OUT2 are set to High (high-side switch ON, low-side switch OFF) or Low (high-side switch OFF, low-side switch ON) by the parallel inputs IN1 and IN2, respectively. In SPI mode there is also the option to control the outputs via the SPI bits SIN1 and SIN2 of the SPI configuration register. To switch to SPI control the bit MUX has to be set to '0'.

In addition, the outputs can be disabled (set to tristate, high- and low-side switch OFF) by the disable input DIS and the bidirectional reset pin  $\overline{\text{ABE}}$ . Disabling sets the device to parallel control

**Table 1** shows the different options for the output control.

### 7.2 H-Bridge or Single Switch Usage

The IC can be set to H-bridge mode or single-switch mode by SPI. This setting changes the behavior of the device in the following features:

- current limiting
- overcurrent shut-down
- open load diagnosis

**Table 1 Functional Truth Table**

| Pos.                                | DIS | $\overline{\text{ABE}}$ | IN1 | IN2 | SPI MUX | SPI SIN1 | SPI SIN2 | OUT1 | OUT2 |
|-------------------------------------|-----|-------------------------|-----|-----|---------|----------|----------|------|------|
| Forward, parallel ctrl.             | L   | H                       | H   | L   | 1       | X        | X        | H    | L    |
| Reverse, parallel ctrl.             | L   | H                       | L   | H   | 1       | X        | X        | L    | H    |
| Free-wheeling low, parallel ctrl.   | L   | H                       | L   | L   | 1       | X        | X        | L    | L    |
| Free-wheeling high, parallel ctrl.  | L   | H                       | H   | H   | 1       | X        | X        | H    | H    |
| Forward, SPI ctrl.                  | L   | H                       | X   | X   | 0       | 1        | 0        | H    | L    |
| Reverse, SPI ctrl.                  | L   | H                       | X   | X   | 0       | 0        | 1        | L    | H    |
| Free-wheeling low, SPI ctrl.        | L   | H                       | X   | X   | 0       | 0        | 0        | L    | L    |
| Free-wheeling high, SPI ctrl.       | L   | H                       | X   | X   | 0       | 1        | 1        | H    | H    |
| Disabled by DIS                     | H   | X                       | X   | X   | X       | X        | X        | Z    | Z    |
| Disabled by $\overline{\text{ABE}}$ | X   | L                       | X   | X   | X       | X        | X        | Z    | Z    |

**Table 2 OUT States**

| OUT | High-Side DMOS | Low-Side DMOS |
|-----|----------------|---------------|
| H   | ON             | OFF           |
| L   | OFF            | ON            |
| Z   | OFF            | OFF           |

### 7.3 Electrical Characteristics Power Stages

#### Electrical Characteristics: Power Stage

$V_S = 5\text{ V}$  to  $28\text{ V}$ ;  $V_{DD} = 5.0\text{ V}$ ,  $T_j = -40\text{ }^{\circ}\text{C}$  to  $150\text{ }^{\circ}\text{C}$ , all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

| Pos. | Parameter | Symbol | Limit Values |      |      | Unit | Test Conditions |
|------|-----------|--------|--------------|------|------|------|-----------------|
|      |           |        | Min.         | Typ. | Max. |      |                 |

#### Power Outputs OUT1, OUT2

|       |                                                      |                                    |      |     |     |    |                                                       |
|-------|------------------------------------------------------|------------------------------------|------|-----|-----|----|-------------------------------------------------------|
| 7.3.1 | Switch on resistance low side                        | $R_{OUT1L}$                        | –    | 125 | –   | mΩ | $I_{OUTx} = 3\text{ A}$ ; $T_j = 25^{\circ}\text{C}$  |
|       |                                                      | $R_{OUT2L}$                        | –    | 215 | 250 |    | $I_{OUTx} = 3\text{ A}$ ; $T_j = 150^{\circ}\text{C}$ |
| 7.3.2 | Switch on resistance high side                       | $R_{OUT1H}$                        | –    | 115 | –   | mΩ | $I_{OUTx} = 3\text{ A}$ ; $T_j = 25^{\circ}\text{C}$  |
|       |                                                      | $R_{OUT2H}$                        | –    | 200 | 240 |    | $I_{OUTx} = 3\text{ A}$ ; $T_j = 150^{\circ}\text{C}$ |
| 7.3.3 | Leakage current                                      | $I_{OUT1(off)}$<br>$I_{OUT2(off)}$ | -200 | –   | 200 | μA | Output stage switched off<br>$V_S = 13\text{ V}$      |
| 7.3.4 | Free-wheel diode forward voltage                     | $U_D$                              | –    | 0.9 | 1.1 | V  | $I_D = 3\text{ A}$                                    |
| 7.3.5 | Free-wheel diode reverse recovery time <sup>1)</sup> | $t_{rr}$                           | –    | –   | 100 | ns | –                                                     |

#### Output Switching Times - Fast Slew Rate

|       |              |                  |     |     |     |    |                                                                   |
|-------|--------------|------------------|-----|-----|-----|----|-------------------------------------------------------------------|
| 7.3.6 | Rise time HS | $t_r(\text{HS})$ | 3.5 | 6.0 | 10  | μs | SPI bit SL='0'<br>$V_S = 8..18\text{ V}$ ; $I_{OUT} = 3\text{ A}$ |
| 7.3.7 | Fall time HS | $t_f(\text{HS})$ | 3.5 | 6.0 | 10  |    |                                                                   |
| 7.3.8 | Rise time LS | $t_r(\text{LS})$ | 3.5 | 6.0 | 8.5 |    |                                                                   |
| 7.3.9 | Fall time LS | $t_f(\text{LS})$ | 3.5 | 6.0 | 8.5 |    |                                                                   |

#### Output Switching Times - Slow Slew Rate

|        |              |                  |    |    |    |    |                                                                   |
|--------|--------------|------------------|----|----|----|----|-------------------------------------------------------------------|
| 7.3.10 | Rise time HS | $t_r(\text{HS})$ | 15 | 30 | 48 | μs | SPI bit SL='1'<br>$V_S = 8..18\text{ V}$ ; $I_{OUT} = 3\text{ A}$ |
| 7.3.11 | Fall time HS | $t_f(\text{HS})$ | 15 | 30 | 48 |    |                                                                   |
| 7.3.12 | Rise time LS | $t_r(\text{LS})$ | 18 | 30 | 48 |    |                                                                   |
| 7.3.13 | Fall time LS | $t_f(\text{LS})$ | 18 | 30 | 48 |    |                                                                   |

#### Output Delay - Parallel Control, Fast Slew Rate

|        |                  |            |   |   |    |    |                                                 |
|--------|------------------|------------|---|---|----|----|-------------------------------------------------|
| 7.3.14 | Output on-delay  | $t_{don}$  | – | – | 12 | μs | $V_S = 8..18\text{ V}$ ; $I_{OUT} = 3\text{ A}$ |
| 7.3.15 | Output off-delay | $t_{doff}$ | – | – | 7  | μs |                                                 |

#### Output Delay - SPI Control, Fast Slew Rate

|        |                  |            |   |   |    |    |                                                 |
|--------|------------------|------------|---|---|----|----|-------------------------------------------------|
| 7.3.16 | Output on-delay  | $t_{don}$  | – | – | 13 | μs | $V_S = 8..18\text{ V}$ ; $I_{OUT} = 3\text{ A}$ |
| 7.3.17 | Output off-delay | $t_{doff}$ | – | – | 12 |    |                                                 |

#### Output Delay - Parallel Control, Slow Slew Rate

|        |                  |            |   |   |    |    |                                                 |
|--------|------------------|------------|---|---|----|----|-------------------------------------------------|
| 7.3.18 | Output on-delay  | $t_{don}$  | – | – | 41 | μs | $V_S = 8..18\text{ V}$ ; $I_{OUT} = 3\text{ A}$ |
| 7.3.19 | Output off-delay | $t_{doff}$ | – | – | 25 |    |                                                 |

#### Output Delay - SPI Control, Slow Slew Rate

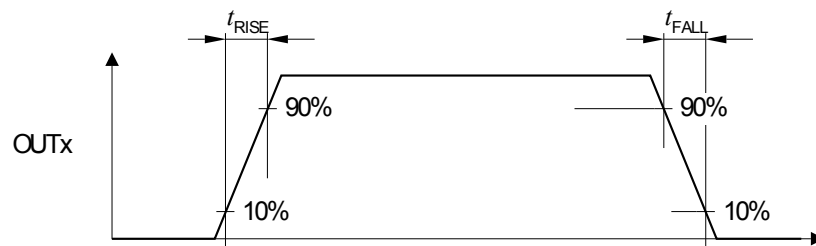
|        |                  |            |   |   |    |    |                                                 |
|--------|------------------|------------|---|---|----|----|-------------------------------------------------|
| 7.3.20 | Output on-delay  | $t_{don}$  | – | – | 42 | μs | $V_S = 8..18\text{ V}$ ; $I_{OUT} = 3\text{ A}$ |
| 7.3.21 | Output off-delay | $t_{doff}$ | – | – | 26 |    |                                                 |

### Electrical Characteristics: Power Stage

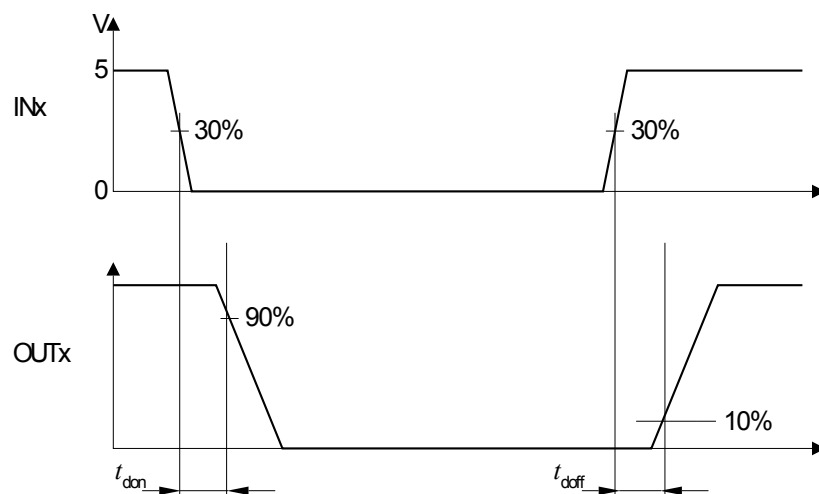
$V_S = 5\text{ V to } 28\text{ V}$ ;  $V_{DD} = 5.0\text{ V}$ ,  $T_j = -40\text{ }^{\circ}\text{C to } 150\text{ }^{\circ}\text{C}$ , all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

| Pos.                           | Parameter                          | Symbol            | Limit Values |      |      | Unit          | Test Conditions                                                            |
|--------------------------------|------------------------------------|-------------------|--------------|------|------|---------------|----------------------------------------------------------------------------|
|                                |                                    |                   | Min.         | Typ. | Max. |               |                                                                            |
| Enable and Disable Delay Times |                                    |                   |              |      |      |               |                                                                            |
| 7.3.22                         | Disable delay time, fast slew rate | $t_{\text{ddis}}$ | —            | 8    | 20   | $\mu\text{s}$ | $V_{\text{S}} = 8..18 \text{ V}; I_{\text{OUT}} = 3 \text{ A}$             |
| 7.3.23                         | Disable delay time, slow slew rate | $t_{\text{ddis}}$ | —            | 38   | 75   |               |                                                                            |
| 7.3.24                         | Enable delay time, fast slew rate  | $t_{\text{del}}$  | —            | 8    | 20   |               |                                                                            |
| 7.3.25                         | Enable delay time, slow slew rate  | $t_{\text{del}}$  | —            | 38   | 75   |               |                                                                            |
| 7.3.26                         | Power on delay time                | $t_{\text{del}}$  | —            | 0.1  | 0.4  | ms            | $V_{\text{S}} = \text{on} \rightarrow \text{output stage active, no load}$ |

1) Not subject to production test - specified by design



**Figure 5 Output Switching Time**



**Figure 6 Output Delay Time – Low-Side FETs**

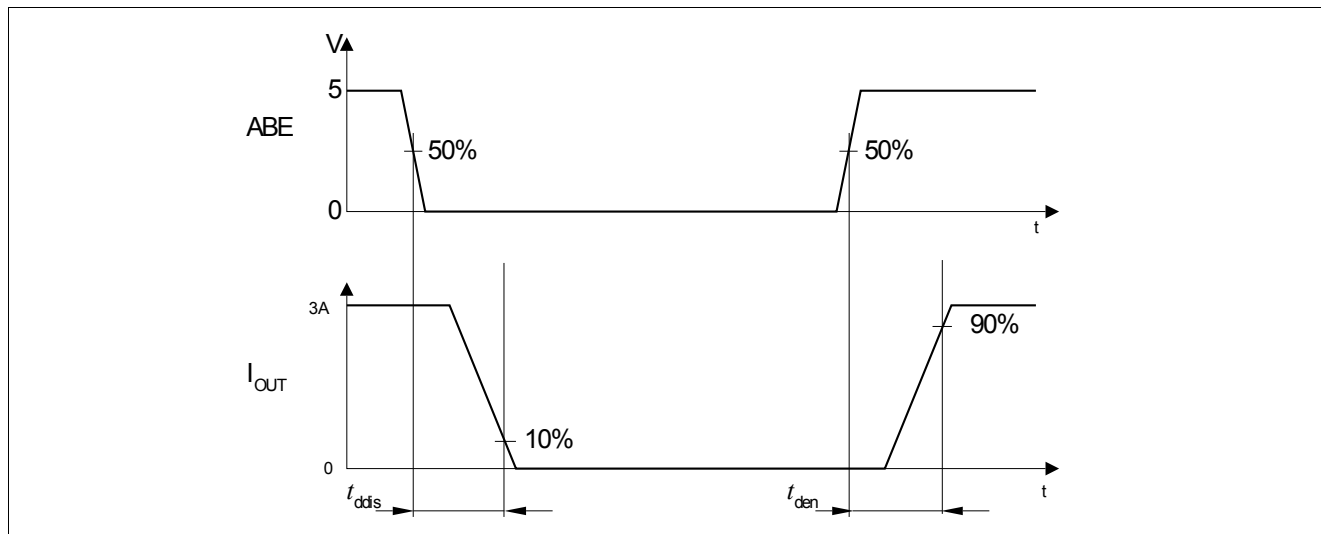


Figure 7 /ABE pin - Enable and Disable Delay Time

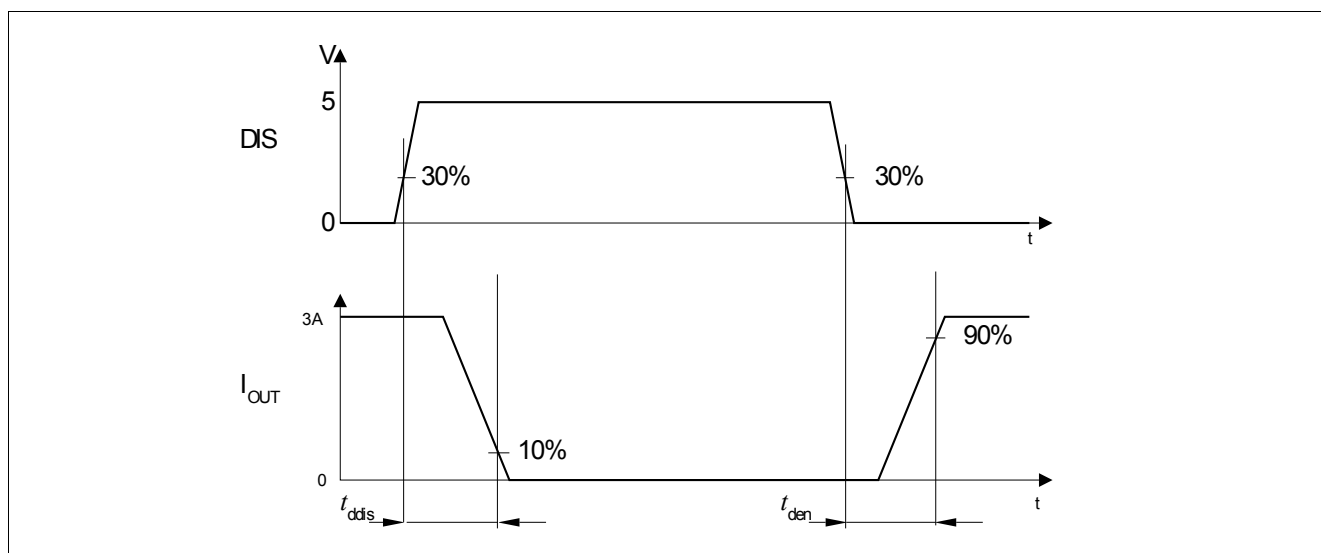


Figure 8 DIS pin - Enable and Disable Delay Time

## 8 Protection and Monitoring

Both output stages of the TLE8209-2SA are equipped with fault diagnostic functions:

- Short to battery voltage (SCB). Can be detected when low side-switches are turned on
- Short to ground (SCG). Can be detected when high side-switches are turned on
- Open load (OL). Can be detected in inactive mode
- Over-temperature (OT). Can be detected in active and inactive mode
- VDD over- and under voltage ([Chapter 5.2](#))
- Battery under voltage detection. Can be detected in active and inactive mode

Individual detection for each output in single switch operation mode (SCB, SCG, OL) is possible. The corresponding diagnostics bits for each failure will be set in the SPI according to [Table 8 "Failure Encoding" on Page 29](#).

### 8.1 Diagnosis in Status Flag Mode

Instead of using the SPI interface for control and diagnosis of the TLE8209-2SA, the device can also be set into status flag mode by connecting pin VDDIO to GND as described in [Chapter 5.3](#).

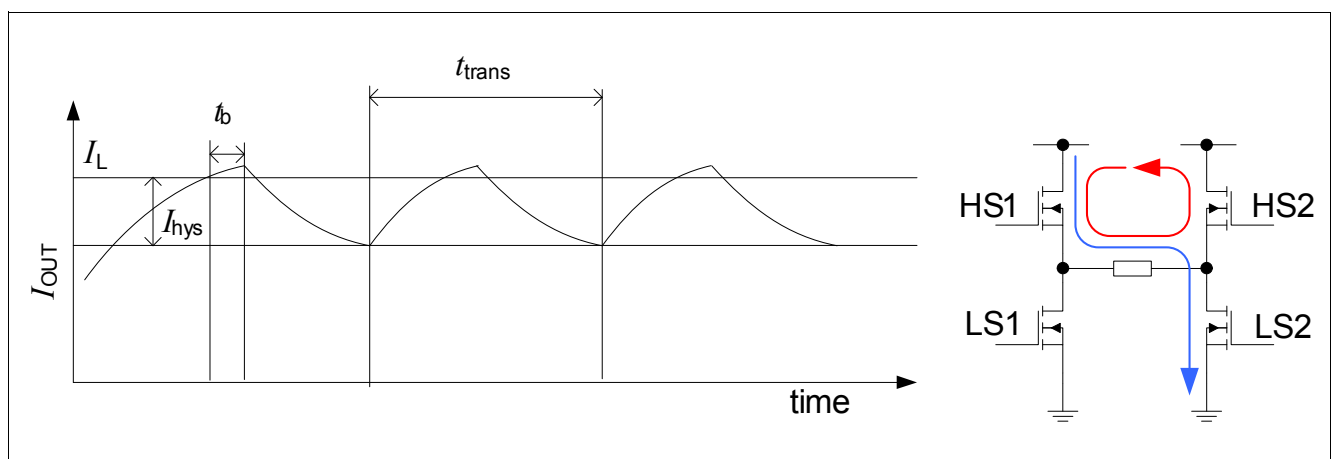
In status flag mode the pin SF will be pulled low in the following cases:

- undervoltage at  $V_S$
- bridge disabled by  $\overline{ABE}$  or DIS
- bridge disabled by VDD monitoring
- bridge disabled by short circuit detection
- overtemperature shut down

SF will not be pulled low if  $V_{DD}$  is below the power on reset threshold ( $V_{DD\_POR}$ ).

### 8.2 Current Limitation

To limit the output current at low power loss, a chopper current limitation is integrated. Current measurement for current limitation is done in the high side path. This requires high side freewheeling in case of active current limitation.



**Figure 9 Chopper Current Limitation**

**Figure 9** shows the behavior of the current limitation for over current detection in HS1. It applies accordingly also for HS2:

When the current in high-side switch of OUT1 (HS1) exceeds the limit  $I_L$  longer than the blanking time  $t_b$ , OUT2 is switched to high (e.g. LS2->OFF, HS2->ON), independent of the input signal at IN2. This leads to a slow-decay current decrease in the load and in HS1. As soon as the current falls below  $I_L - I_{hys}$ , OUT2 is switched back to normal

operation, i.e. the outputs follow the inputs according to the truth table. The current limit  $I_L$  can be programmed to four different values by setting the SPI bits CL1 and CL2 in the SPI configuration register. To avoid high chopper frequencies the time between two transients  $t_{trans}$  is limited.

Current limitation is available in H-bridge operation mode, not in single switch operation mode. This means, that the current limit, current limit hysteresis and blanking time has no effect in single switch operation mode.

### 8.3 Temperature Dependent Current Reduction

For  $T_{ILR} < T_j < T_{SD}$  the current limit decreases from  $I_L$  as set by the SPI to  $I_{L\_TSD} = 2.5\text{ A}$  typ. as shown in Figure 10.

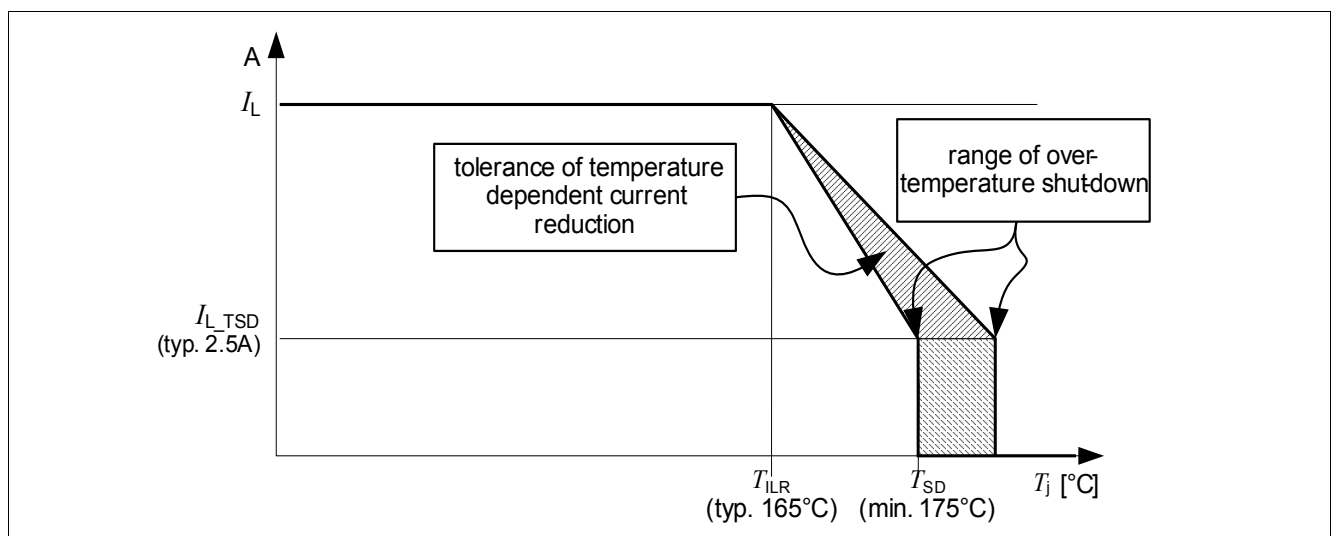


Figure 10 Temperature Dependent Current Reduction

### 8.4 Short Circuit to Ground

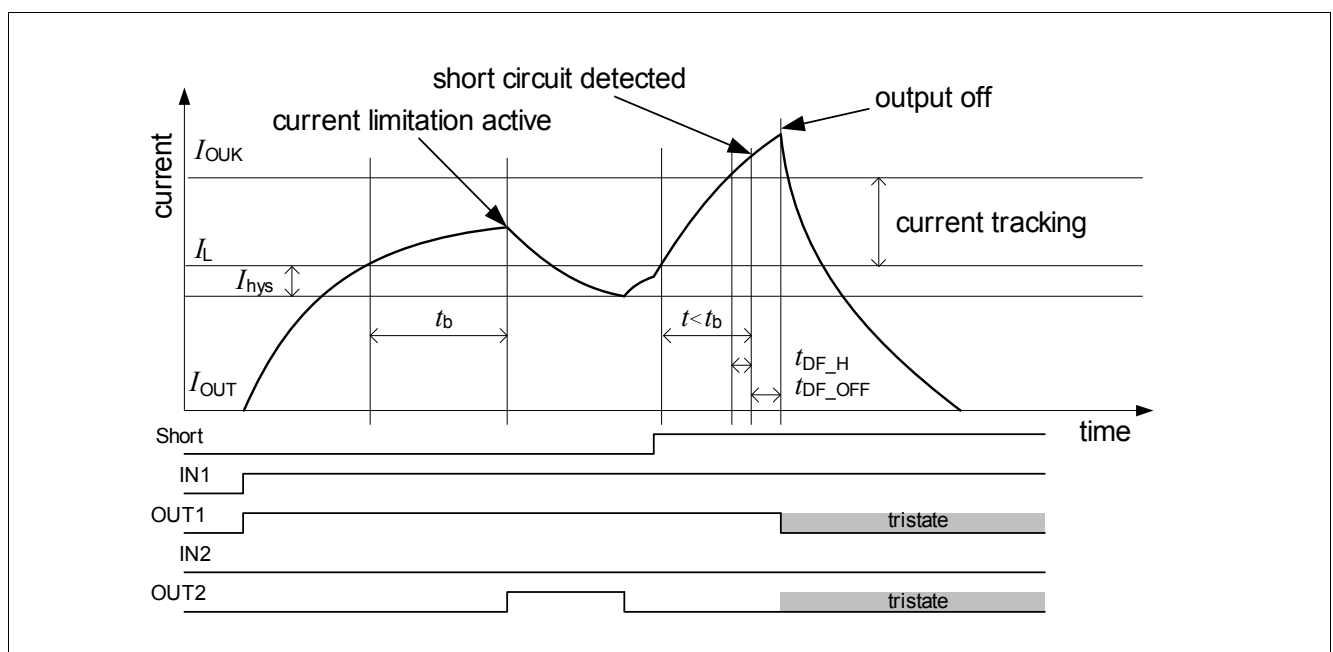


Figure 11 Short to Ground Detection

The short circuit to ground detection is activated when the current through one of the high side switches rises over the threshold  $I_{\text{OUC}}$  and remains higher than  $I_{\text{OUC}}$  for at least the filter time  $t_{\text{DF\_H}}$  within the blanking time  $t_b$ .

The output stage in which the short circuit was detected will be switched off within  $t_{\text{DF\_OFF}}$ .

In H-bridge mode also the other output will be switched off after a short delay of  $t_{\text{DF\_del}}$ .

In single switch mode only the affected output will be switched off.

## 8.5 Short Circuit to Battery

A short circuit to battery is detected in the same way as a short circuit to ground, only in the low side switch instead of the high side switch.

## 8.6 Short Circuit across the Load

Short circuit over load is indicated by two failures - short circuit to ground on one output and short circuit to battery on the other output. Both failure bits will be set in the SPI diagnostics register. Both output stages will be turned off.

## 8.7 Overtemperature

In case of high DC-currents, insufficient cooling or high ambient temperature, the chip temperature may rise above the thermal shut-down temperature  $T_{\text{SD}}$  (see [Figure 10](#)). In that case, all output transistors are turned off.

## 8.8 Undervoltage Shut-Down

If the supply voltage at the VS pins falls below the undervoltage detection threshold  $V_{\text{UV\_OFF}}$ , the outputs switches are turned off. As soon as  $V_{\text{S}}$  rises above  $V_{\text{UV\_ON}}$  again, the device is returning to normal operation.

## 8.9 Open Load Diagnosis

Open load diagnosis is only possible if outputs are switched off by DIS or  $\overline{\text{ABE}}$ . The diagnostic current sources are deactivated in status flag mode. Diagnostic current sources are disconnected if outputs are active. That means that the diagnostic current sources are also disconnected if the outputs are deactivated due to short circuit. The open load detection in H-bridge mode is different from the open load detection in single switch mode.

### Open Load Detection in H-Bridge mode

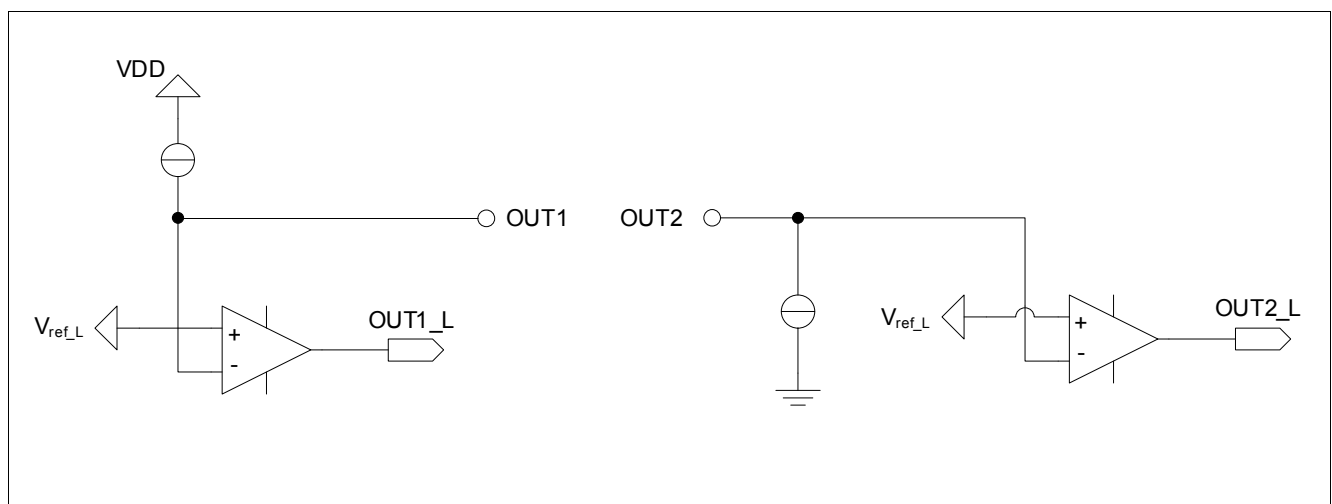
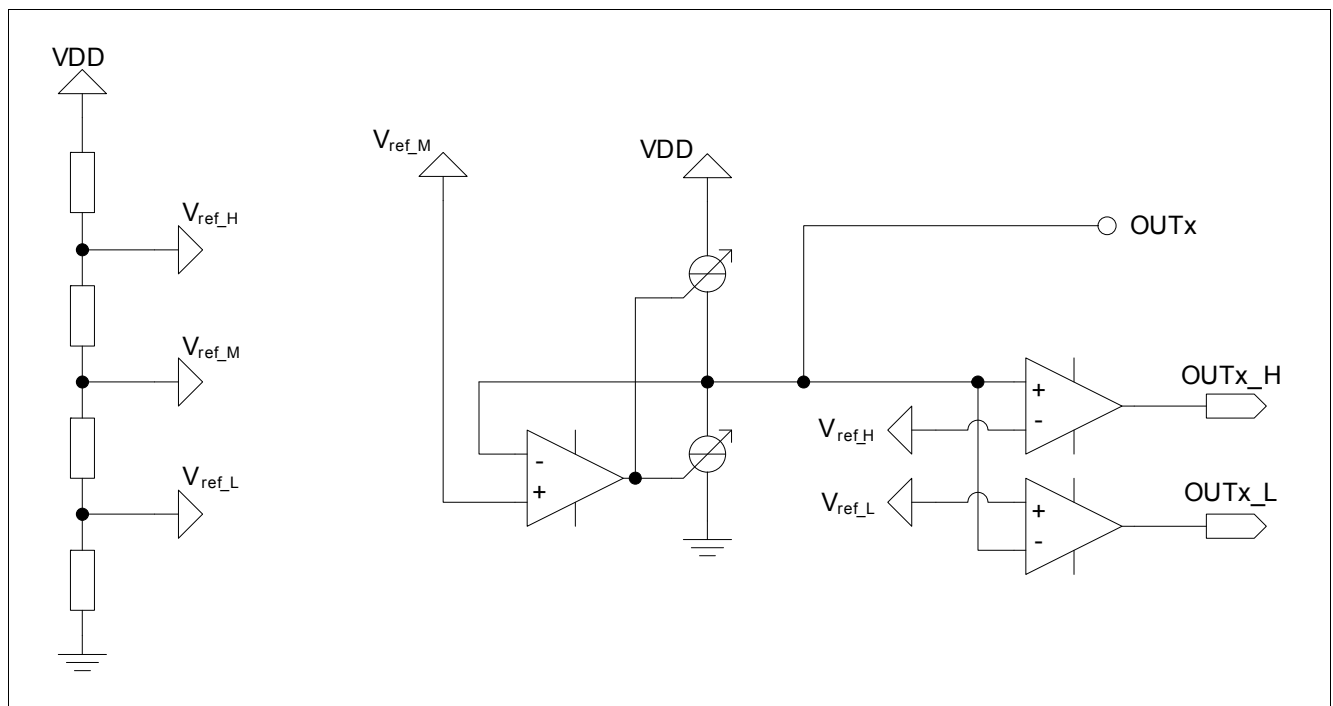


Figure 12 Open Load Detection in H-Bridge Mode

**Table 3 Open Load Detection in H-Bridge Mode**

| VOUT1          | OUT1_L | VOUT2          | OUT2_L | Diagnostic | Comment                       |
|----------------|--------|----------------|--------|------------|-------------------------------|
| $< V_{ref\_L}$ | H      | $< V_{ref\_L}$ | H      | Load o.k.  | pull down current is stronger |
| $< V_{ref\_L}$ | H      | $> V_{ref\_L}$ | L      | Load o.k.  | transient area                |
| $> V_{ref\_L}$ | L      | $< V_{ref\_L}$ | H      | Open Load  |                               |
| $> V_{ref\_L}$ | L      | $> V_{ref\_L}$ | L      | Load o.k.  | transient area                |

### Open Load Detection in Single Switch Mode


**Figure 13 Open Load Detection in Single Switch Mode**
**Table 4 Open Load Detection in Single Switch Mode**

| VOUTx (OFF State)                    | OUTx_H | OUTx_L | Diagnostic | Comment        |
|--------------------------------------|--------|--------|------------|----------------|
| $V_{OUTx} < V_{ref\_L}$              | L      | H      | o.k.       | Load to ground |
| $V_{ref\_L} < V_{OUTx} < V_{ref\_H}$ | L      | L      | Open Load  | Output open    |
| $V_{OUTx} > V_{ref\_H}$              | H      | L      | o.k.       | Load to $V_S$  |

## 8.10 Electrical Characteristics

### Electrical Characteristics: Protection and Monitoring

$V_S = 5\text{ V to } 28\text{ V}$ ;  $V_{DD} = 5.0\text{ V}$ ,  $T_j = -40\text{ °C to } 150\text{ °C}$ , all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

| Pos. | Parameter | Symbol | Limit Values |      |      | Unit | Test Conditions |
|------|-----------|--------|--------------|------|------|------|-----------------|
|      |           |        | Min.         | Typ. | Max. |      |                 |

#### Chopper Current Limitation

|        |                          |             |     |      |      |    |                                                                            |
|--------|--------------------------|-------------|-----|------|------|----|----------------------------------------------------------------------------|
| 8.10.1 | Current Limit            | $ I_{L1} $  | 1.0 | 1.5  | 2.0  | A  | -40 °C < $T_j$ < $T_{ILR}$<br>Dependent on SPI setting; Default = $I_{L3}$ |
| 8.10.2 |                          | $ I_{L2} $  | 3.3 | 4.0  | 4.7  |    |                                                                            |
| 8.10.3 |                          | $ I_{L3} $  | 5.5 | 6.6  | 7.7  |    |                                                                            |
| 8.10.4 |                          | $ I_{L4} $  | 7.7 | 8.6  | 10.0 |    |                                                                            |
| 8.10.5 | Current Limit Hysteresis | $I_{hys}$   | 0   | 0.25 | 0.40 | A  | -40 °C < $T_j$ < $T_{ILR}$                                                 |
| 8.10.6 | Blanking time            | $t_b$       | 8   | 11   | 15   | μs | —                                                                          |
| 8.10.7 | Time between transients  | $t_{trans}$ | 90  | —    | 130  | μs | —                                                                          |

#### Temperature Dependent Current Limitation<sup>1)</sup>

|         |                                                  |                    |     |     |     |    |   |
|---------|--------------------------------------------------|--------------------|-----|-----|-----|----|---|
| 8.10.8  | Current Limit at $T_{SD}$                        | $I_{L\_TSD}$       | 1.4 | 2.5 | 3.6 | A  | — |
| 8.10.9  | Start of current limit reduction                 | $T_{ILR}$          | 150 | 165 | —   | °C | — |
| 8.10.10 | Thermal shut-down                                | $T_{SD}$           | 175 | —   | —   | °C | — |
| 8.10.11 | Range of temperature dependent current reduction | $T_{SD} - T_{ILR}$ | 20  | 25  | 30  | °C | — |

#### Short Circuit Detection to GND

|         |                                         |                          |     |      |      |   |                                                                                                   |
|---------|-----------------------------------------|--------------------------|-----|------|------|---|---------------------------------------------------------------------------------------------------|
| 8.10.12 | Short circuit detection<br>current (HS) | $ I_{OUKH1} $            | 2.5 | 5.0  | 6.5  | A | -40 °C < $T_j$ < $T_{ILR}$<br>Dependent on SPI-<br>setting for $ I_L $ ; Default =<br>$I_{OUKH3}$ |
| 8.10.13 |                                         | $ I_{OUKH2} $            | 5.0 | 7.3  | 10   |   |                                                                                                   |
| 8.10.14 |                                         | $ I_{OUKH3} $            | 7.5 | 9.5  | 11.5 |   |                                                                                                   |
| 8.10.15 |                                         | $ I_{OUKH4} $            | 9.5 | 11.8 | 17.4 |   |                                                                                                   |
| 8.10.16 | Current tracking                        | $ I_{OUKH1}  -  I_{L1} $ | 2.0 | 3.5  | 5.0  | A |                                                                                                   |
| 8.10.17 |                                         | $ I_{OUKH2}  -  I_{L2} $ | 2.0 | 3.3  | 5.0  |   |                                                                                                   |
| 8.10.18 |                                         | $ I_{OUKH3}  -  I_{L3} $ | 2.0 | 3.2  | 5.0  |   |                                                                                                   |
| 8.10.19 |                                         | $ I_{OUKH4}  -  I_{L4} $ | 1.8 | 3.0  | 5.0  |   |                                                                                                   |

#### Short Circuit Detection to VS

|         |                                         |                          |     |     |      |   |                                                                                                   |
|---------|-----------------------------------------|--------------------------|-----|-----|------|---|---------------------------------------------------------------------------------------------------|
| 8.10.20 | Short circuit detection<br>current (LS) | $ I_{OUKL1} $            | 2.5 | 4.6 | 6.5  | A | -40 °C < $T_j$ < $T_{ILR}$<br>Dependent on SPI-<br>setting for $ I_L $ ; Default =<br>$I_{OUKL3}$ |
| 8.10.21 |                                         | $ I_{OUKL2} $            | 5.0 | 7.9 | 10   |   |                                                                                                   |
| 8.10.22 |                                         | $ I_{OUKL3} $            | 7.5 | 9.8 | 11.5 |   |                                                                                                   |
| 8.10.23 |                                         | $ I_{OUKL4} $            | 9.5 | 14  | 17.4 |   |                                                                                                   |
| 8.10.24 | Current tracking                        | $ I_{OUKL1}  -  I_{L1} $ | 1.5 | 3.0 | 5.0  | A |                                                                                                   |
| 8.10.25 |                                         | $ I_{OUKL2}  -  I_{L2} $ | 2.0 | 4.0 | 5.5  |   |                                                                                                   |
| 8.10.26 |                                         | $ I_{OUKL3}  -  I_{L3} $ | 1.8 | 3.5 | 5.5  |   |                                                                                                   |
| 8.10.27 |                                         | $ I_{OUKL4}  -  I_{L4} $ | 2.0 | 5.1 | 8.0  |   |                                                                                                   |

## Protection and Monitoring

### Electrical Characteristics: Protection and Monitoring

$V_S = 5\text{ V to }28\text{ V}$ ;  $V_{DD} = 5.0\text{ V}$ ,  $T_j = -40\text{ °C to }150\text{ °C}$ , all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

| Pos.                           | Parameter                                                              | Symbol                 | Limit Values         |                |                      | Unit | Test Conditions          |
|--------------------------------|------------------------------------------------------------------------|------------------------|----------------------|----------------|----------------------|------|--------------------------|
|                                |                                                                        |                        | Min.                 | Typ.           | Max.                 |      |                          |
| Short Circuit Detection Timing |                                                                        |                        |                      |                |                      |      |                          |
| 8.10.28                        | Delay time for fault detection                                         | $t_{DF\_H}, t_{DF\_L}$ | 1                    | 2              | 5                    | μs   | –                        |
| 8.10.29                        | Time from detected fault to high impedance of output <sup>1)</sup>     | $t_{DF\_OFF}$          | –                    | –              | 4                    | μs   | –                        |
| 8.10.30                        | Delay time between switching off of the output stages in short circuit | $t_{DF\_del}$          | 5                    | 17             | 40                   | μs   | –                        |
| Open Load                      |                                                                        |                        |                      |                |                      |      |                          |
| 8.10.31                        | Open Load Diagnostic Filter Time <sup>1)</sup>                         | $t_{OL\_DIAG}$         | 60                   | –              | 135                  | μs   | –                        |
| 8.10.32                        | Low Diagnosis Threshold                                                | $V_{ref\_L}$           | 0.4 * $V_{DD}$ - 0.2 | 0.4 * $V_{DD}$ | 0.4 * $V_{DD}$ + 0.2 | V    | –                        |
| 8.10.33                        | High Diagnosis Threshold                                               | $V_{ref\_H}$           | 0.8 * $V_{DD}$ - 0.2 | 0.8 * $V_{DD}$ | 0.8 * $V_{DD}$ + 0.2 | V    | –                        |
| 8.10.34                        | Diagnosis Bias Voltage                                                 | $V_{ref\_M}$           | 0.6 * $V_{DD}$ - 0.2 | 0.6 * $V_{DD}$ | 0.6 * $V_{DD}$ + 0.2 | V    | –                        |
| 8.10.35                        | Positive Diagnostic Current (pull down current source)                 | $I_{DIA\_P}$           | 300                  | 620            | 980                  | μA   | $V_{OUTx} = 14\text{ V}$ |
| 8.10.36                        |                                                                        |                        | 270                  | 610            | 980                  | μA   | $V_{OUTx} = V_{ref\_H}$  |
| 8.10.37                        | Negative Diagnostic Current                                            | $I_{DIA\_N}$           | -350                 | -240           | -100                 | μA   | $V_{OUTx} = 0\text{ V}$  |
| 8.10.38                        |                                                                        |                        | -350                 | -210           | -80                  | μA   | $V_{OUTx} = V_{ref\_L}$  |
| 8.10.39                        | Ratio of current sources (Pos/Neg)                                     | $Ratio_{I\_DIA}$       | 2                    | 2.9            | 4                    | –    | –                        |
| Undervoltage                   |                                                                        |                        |                      |                |                      |      |                          |
| 8.10.40                        | Undervoltage at $V_S$                                                  | $V_{UV\ OFF}$          | 3.1                  | 3.7            | 4.4                  | V    | Switch off threshold     |
|                                |                                                                        | $V_{UV\ ON}$           | 3.3                  | 3.9            | 4.6                  | V    | Switch on threshold      |
|                                |                                                                        | $V_{UV\ HY}$           | 100                  | 200            | 400                  | mV   | Hysteresis               |
| 8.10.41                        | VS Undervoltage Detection Filter Time <sup>1)</sup>                    | $t_{UV}$               | –                    | –              | 1.5                  | μs   |                          |

1) Not subject to production test; specified by design.

## 9 SPI Interface

The serial SPI interface establishes a communication link between TLE8209-2SA and the systems microcontroller. The TLE8209-2SA always operates in slave mode whereas the controller provides the master function. The maximum baud rate is 2 MBaud.

By applying an active slave select signal at  $\overline{SS}$  the TLE8209-2SA is selected by the SPI-master. SI is the data input (Slave In), SO the data output (Slave Out). Via SCK (Serial Clock Input) the SPI-clock is provided by the master. In case of inactive slave select signal (High) the data output SO goes into tristate.

The first two bits of an instruction may be used to establish an extended device-addressing. This gives the opportunity to operate up to 4 Slave-devices sharing one common  $\overline{SS}$  signal from the Master-Unit (see [Figure 16](#)).

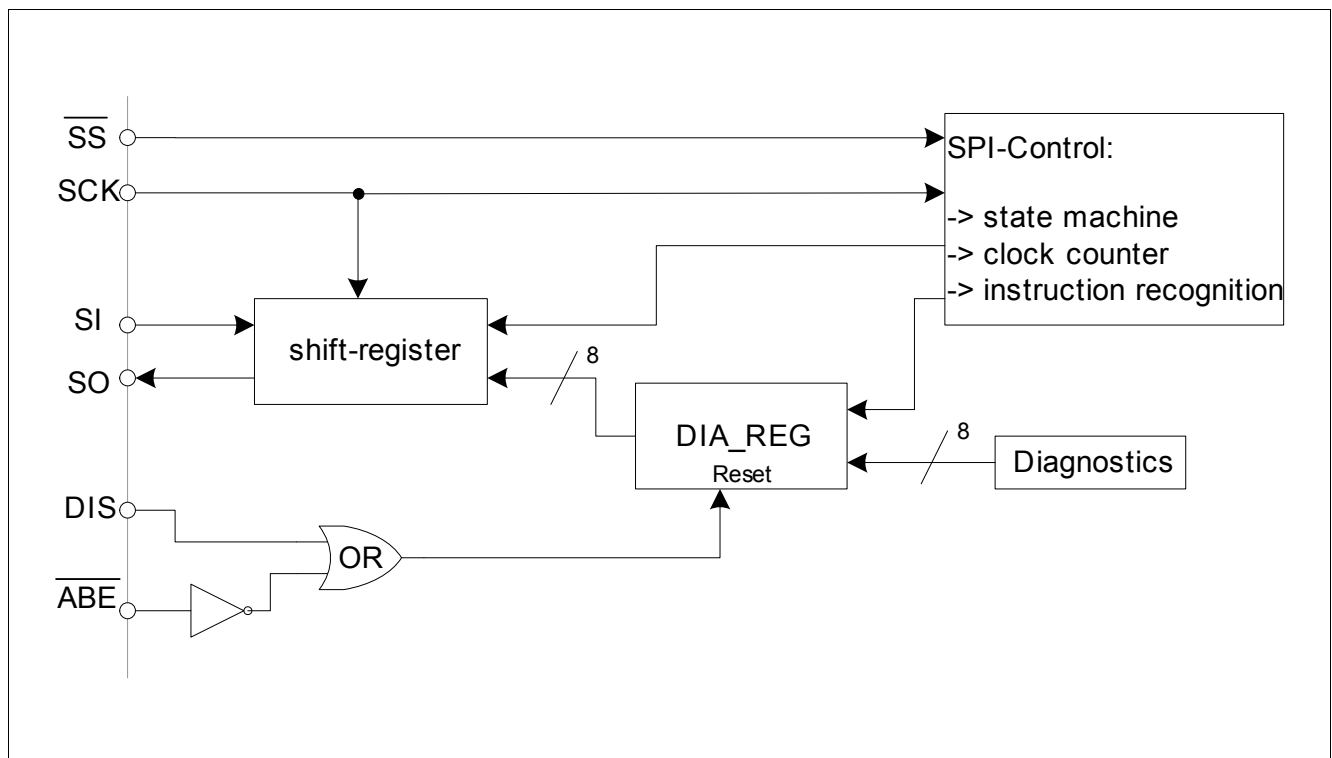


Figure 14 SPI Block Diagram

### 9.1 General SPI Characteristics

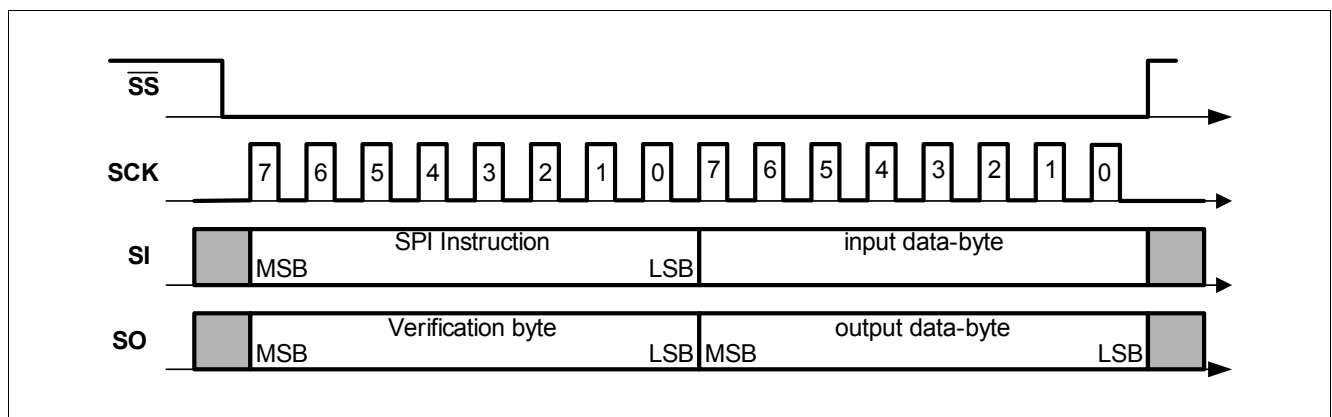
1. During active reset conditions the SPI is driven into its default state. The output SO is set to high impedance (tristate). When reset becomes inactive, the state machine enters into a wait state for the next instruction.
2. If the slave select signal at SS is inactive (high), the state machine is forced to wait for the following instruction.
3. During active (low) state of the select signal SS the falling edge of the serial clock signal SCK will be used to latch the input data at SI. Output data at SO are driven with the rising edge of SCK. Further processing of the data according to the instruction (i.e. modification of internal registers) will be triggered by the rising edge of the SS signal.
4. In order to establish the option of extended addressing the upper two bits of the instruction byte (i.e. the first two SI bits of a frame) are reserved to send a chip address. To avoid a bus conflict the output SO will remain tristate during the addressing phase of a frame (i.e. until the address bits are recognized as a valid chip

address). If the chip address does not match, the according frame will be ignored and SO remains tristate for the complete frame.

5. Verification byte: Simultaneously to the receipt of an SPI instruction the TLE8209-2SA transmits a verification byte via the output SO to the controller. This byte indicates regular or irregular operation of the SPI. It contains an initial bit pattern and a flag indicating an invalid instruction of the previous access.
6. On a read access the data bits at the SPI input SI are rejected. During a valid write access the SPI will transmit the data byte "00hex" at the output SO after having sent the verification byte.
7. An instruction is invalid if one of the following conditions is fulfilled:
  - an unused instruction code is detected (see tables with SPI instructions).
  - the previous transmission is not completed in terms of internal data processing.
  - the number of SPI clock pulses (falling edge) counted during active SS differs from exactly 16 clock pulses.
 If an unused instruction code occurs, the data byte "FF<sub>hex</sub>" (no error) will be transmitted after having sent the verification byte. This transmission takes place within the same SPI-frame that contained the unused instruction byte.  
 If an invalid instruction is detected, bit TRANS\_F in the following verification byte (next SPI-transmission) is set to HIGH. The TRANS\_F bit must not be cleared before it has been sent to the microcontroller.

## 9.2 SPI Communication

The 16 input bits consist of the SPI instruction byte and an input data byte. The 16 output bits consist of the verification byte and the output data byte (see also [Figure 15](#)). The definition of these bytes is given in the subsequent sections. The access mode of the registers is described in the column "Type" (r = read, w = write).



**Figure 15** SPI Communication

### 9.2.1 Instruction Byte

The upper 2 bit of the instruction byte contain the chip address. The chip address of the TLE8209-2SA is '00'. During read access, the output data according to the register requested in the instruction byte are applied to SO within the same SPI frame. That means, the output data corresponding to an instruction byte sent during one SPI frame are transmitted to SO during the same SPI-frame

Table 5 SPI Instruction Format

| 7     | 6     | 5      | 4      | 3      | 2      | 1      | 0      |
|-------|-------|--------|--------|--------|--------|--------|--------|
| CPAD1 | CPAD0 | INSTR5 | INSTR4 | INSTR3 | INSTR2 | INSTR1 | INSTR0 |

| Field    | Bits | Type | Description                     |
|----------|------|------|---------------------------------|
| CPAD1:0  | 7:6  | w    | Chip Address (00 <sub>B</sub> ) |
| INSTR5:0 | 5:0  | w    | SPI Instruction (encoding)      |

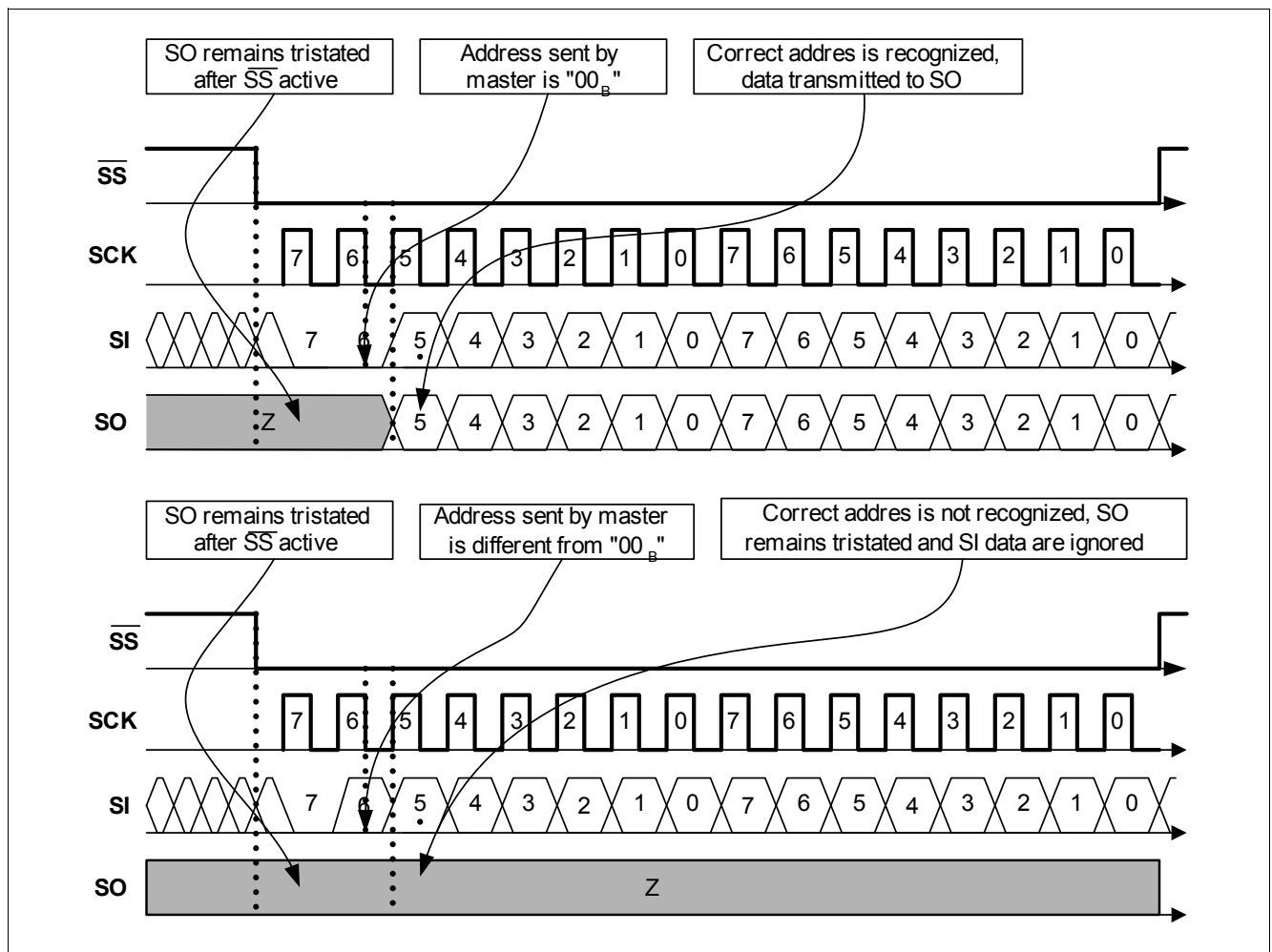


Figure 16 Bus Arbitration by Chip Address

**Table 6 SPI Instruction Set**

| Command                | SPI Instruction Byte | Description                                                    |
|------------------------|----------------------|----------------------------------------------------------------|
| RD_ID                  | 0000 0000            | Read identifier                                                |
| RD_REV                 | 0000 0011            | Read version                                                   |
| RD_DIA                 | 0000 1001            | Read diagnostics register                                      |
| RD_CONFIG              | 0011 0000            | Read power stage configuration                                 |
| RD_STATCON             | 0011 1100            | Read VDD monitoring status                                     |
| WR_CONFIG              | 0010 1000            | Write power stage configuration                                |
| WR_STATCON             | 0001 1000            | Write VDD monitoring status                                    |
| all other instructions | 00xx xxxx            | Unused - TRANS_F is set to high, ff_hex is sent as data bit.   |
| all other chip addr.   | xxxx xxxx            | Invalid address - SO remains tristate during entire SPI-frame. |

### 9.2.2 Verification Byte

**Table 7 Verification Byte Format**

| 7    | 6    | 5    | 4    | 3    | 2    | 1    | 0       |
|------|------|------|------|------|------|------|---------|
| VER6 | VER5 | VER4 | VER3 | VER2 | VER1 | VER0 | TRANS_F |

| Field   | Bits | Type | Description                                                                                                                             |
|---------|------|------|-----------------------------------------------------------------------------------------------------------------------------------------|
| VER6    | 7    | r    | Fixed to tristate (Z)                                                                                                                   |
| VER5    | 6    | r    | Fixed to tristate (Z)                                                                                                                   |
| VER4    | 5    | r    | Fixed to high (1)                                                                                                                       |
| VER3    | 4    | r    | Fixed to low (0)                                                                                                                        |
| VER2    | 3    | r    | Fixed to high (1)                                                                                                                       |
| VER1    | 2    | r    | Fixed to low (0)                                                                                                                        |
| VER0    | 1    | r    | Fixed to high (1)                                                                                                                       |
| TRANS_F | 0    | r    | Transfer failure:<br>1 <sub>B</sub> Error detected during previous transfer<br>0 <sub>B</sub> Previous transfer was recognized as valid |

### 9.2.3 Device Identifier and Revision

The IC's identifier (device ID) and revision number are used for production test purposes and features plug & play functionality depending on the systems software release. The two numbers are read-only accessible via the SPI-instructions RD\_ID and RD\_REV as described in [Section 9.2.1](#). The device ID is defined to allow identification of different IC-types by software and is fixed for the TLE8209-2SA.

The revision number may be utilized to distinguish different states of hardware and is updated with each redesign of the TLE8209-2SA. It is divided into an upper 4 bit field reserved to define revisions (SWR) corresponding to specific software releases and a lower 4 bit field utilized to identify the actual mask set revision (MSR).

## ID\_REG

### Device Identifier

| 7   | 6   | 5   | 4   | 3   | 2   | 1   | 0   |
|-----|-----|-----|-----|-----|-----|-----|-----|
| ID7 | ID6 | ID5 | ID4 | ID3 | ID2 | ID1 | ID0 |

| Field | Bits | Type | Description                             |
|-------|------|------|-----------------------------------------|
| ID7:0 | 7:0  | r    | <b>Device-ID</b><br>TLE8209-2SA: DE hex |

## REV\_REG

### Device Revision

| 7    | 6    | 5    | 4    | 3    | 2    | 1    | 0    |
|------|------|------|------|------|------|------|------|
| SWR3 | SWR2 | SWR1 | SWR0 | MSR3 | MSR2 | MSR1 | MSR0 |

| Field  | Bits | Type | Description                                |
|--------|------|------|--------------------------------------------|
| SWR3:0 | 7:4  | r    | Revision corresponding to software release |
| MSR3:0 | 3:0  | r    | Revision corresponding to mask set         |

## 9.2.4 Diagnostics Register

### DIA\_REG

#### Diagnostics Register

Reset Value: x111 1111<sub>B</sub>

| 7                                  | 6  | 5       | 4       | 3     | 2     | 1     | 0     |
|------------------------------------|----|---------|---------|-------|-------|-------|-------|
| $\overline{\text{ABE}}/\text{DIS}$ | OT | CurrRed | CurrLim | DIA21 | DIA20 | DIA11 | DIA10 |

| Field                              | Bits | Type | Description                                                                            |
|------------------------------------|------|------|----------------------------------------------------------------------------------------|
| $\overline{\text{ABE}}/\text{DIS}$ | 7    | r    | Is set to "0" in case of $\overline{\text{ABE}} = \text{L}$ or $\text{DIS} = \text{H}$ |
| OT                                 | 6    | r    | Is set to "0" in case of over temperature                                              |
| CurrRed                            | 5    | r    | Is set to "0" in case of temperature dependent current limitation                      |
| CurrLim                            | 4    | r    | Is set to "0" in case of current limitation                                            |
| DIA21                              | 3    | r    | Diagnosis-Bit2 of OUT2                                                                 |
| DIA20                              | 2    | r    | Diagnosis-Bit1 of OUT2                                                                 |
| DIA11                              | 1    | r    | Diagnosis-Bit2 of OUT1                                                                 |
| DIA10                              | 0    | r    | Diagnosis-Bit1 of OUT1                                                                 |

**Table 8 Failure Encoding**

| ABE/DIS | DIA21 | DIA20 | DIA11 | DIA10 | Description                                 | Comment     |
|---------|-------|-------|-------|-------|---------------------------------------------|-------------|
| X       | 1     | 1     | 1     | 1     | no failure                                  |             |
| 1       | X     | X     | 0     | 1     | short circuit to battery at OUT1 (SCB1)     | latched     |
| 1       | X     | X     | 1     | 0     | short circuit to ground at OUT1 (SCG1)      | latched     |
| 1       | X     | X     | 1     | 1     | no error detected at OUT1                   |             |
| 1       | 0     | 1     | X     | X     | short circuit to battery at OUT2 (SCB2)     | latched     |
| 1       | 1     | 0     | X     | X     | short circuit to ground at OUT2 (SCG2)      | latched     |
| 1       | 1     | 1     | X     | X     | no error detected at OUT2                   |             |
| 1       | 0     | 1     | 1     | 0     | short circuit accross load (HS1+LS2 active) | latched     |
| 1       | 1     | 0     | 0     | 1     | short circuit accross load (HS2+LS1 active) | latched     |
| X       | 0     | 0     | 0     | 0     | Undervoltage at pin VS                      | not latched |
| 0       | 1     | 1     | 0     | 0     | open load (H-Bridge)                        | latched     |
| 0       | 1     | 1     | X     | 0     | open load at OUT1 (single switch operation) | latched     |
| 0       | 1     | 1     | 0     | X     | open load at OUT2 (single switch operation) | latched     |

**Note:**

The bit  $\overline{\text{ABE}}$ /DIS shows directly the status of inputs  $\overline{\text{ABE}}$  and DIS. It is set to '0' if the power stages are disabled by  $\overline{\text{ABE}}$  or DIS.

The bits OT, CurrRed and CurrLim are latched. They will be reset with each read access. If the failure condition is still present the according bits are set again.

Undervoltage at VS is reported and the outputs are switched off as long as the undervoltage condition is present. The previous setting of the DIAx bits is masked but not reset. Once the supply voltage is back in the operating range the diagnostic bits DIAxx will return to their setting before VS undervoltage. The outputs will return to normal operation.

Detection of short circuit will switch of the output stages. In single half bridge operation only the affected output is switched off. In H-Bridge mode both outputs are shut down. The outputs remain off until the failure condition is removed and the diagnosis register is reset.

A short across the load may also be reported as SCG at one output and SCB at the other.

The diagnostic information DIAxx in the SPI interface is reset in the following cases:

- Read out of DIA\_REG: only bit 4, 5 and 6 will be reset
- Enabling or disabling of the bridge via  $\overline{\text{ABE}}$  or DIS
- Undervoltage at VDD
- Reset command via SPI

## 9.2.5 Configuration Register

### CONFIG\_REG

#### Configuration Register

Reset Value: 1111 1010<sub>B</sub>

| 7    | 6   | 5    | 4    | 3   | 2   | 1     | 0  |
|------|-----|------|------|-----|-----|-------|----|
| MODE | MUX | SIN1 | SIN2 | CL1 | CL2 | RESET | SL |

| Field | Bits | Type | Description                                                                           |
|-------|------|------|---------------------------------------------------------------------------------------|
| MODE  | 7    | wr   | '1': H-bridge mode<br>'0': single output stages (for current levels 1 to 3 only)      |
| MUX   | 6    | wr   | '1': control by parallel inputs IN1 and IN2<br>'0': control by SPI bits SIN1 and SIN2 |
| SIN1  | 5    | wr   | control of OUT1 if MUX='0'                                                            |
| SIN2  | 4    | wr   | control of OUT2 if MUX='0'                                                            |
| CL1   | 3    | wr   | current limitation level (see table below)                                            |
| CL2   | 2    | wr   | current limitation level (see table below)                                            |
| RESET | 1    | wr   | '0': reset of digital logic                                                           |
| SL    | 0    | wr   | slew rate setting<br>'1': slow<br>'0': fast                                           |

**Table 9 Current Limitation Levels**

| CL1 | CL2 | Current Level | Typical Current |
|-----|-----|---------------|-----------------|
| 0   | 0   | 1             | 1.5A            |
| 0   | 1   | 2             | 4.0A            |
| 1   | 0   | 3 (default)   | 6.6A            |
| 1   | 1   | 4             | 8.6A            |

## 9.2.6 STATCON Register

### STATCON\_REG

#### STATCON Register

Reset Value: 1101 1xxx<sub>B</sub>

| 7       | 6       | 5       | 4       | 3       | 2       | 1       | 0       |
|---------|---------|---------|---------|---------|---------|---------|---------|
| CONFIG2 | CONFIG1 | CONFIG0 | DIACLR2 | DIACLR1 | STATUS2 | STATUS1 | STATUS0 |

| Field   | Bits | Type | Description                                                                                                                |
|---------|------|------|----------------------------------------------------------------------------------------------------------------------------|
| CONFIG2 | 7    | wr   | VDD threshold test mode<br>'1': VDD monitoring in normal operation<br>'0': VDD thresholds are changed according to CONFIG1 |

## SPI Interface

| Field   | Bits | Type | Description                                                                                                                                                                                                       |
|---------|------|------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| CONFIG1 | 6    | wr   | changes thresholds in VDD threshold test mode (CONFIG2='0')<br>'1': increase lower threshold of VDD monitoring to test switch off path<br>'0': decrease upper threshold of VDD monitoring to test switch off path |
| CONFIG0 | 5    | wr   | latch function for overvoltage at VDD<br>'1': overvoltage at VDD latched<br>'0': overvoltage at VDD not latched                                                                                                   |
| DIACLR2 | 4    | wr   | '0': clears diagnosis of OUT2<br>always returns '1' at read access                                                                                                                                                |
| DIACLR1 | 3    | wr   | '0': clears diagnosis of OUT1<br>always returns '1' at read access                                                                                                                                                |
| STATUS2 | 2    | r    | returns level at $\overline{ABE}$                                                                                                                                                                                 |
| STATUS1 | 1    | r    | '0': under voltage at VDD<br>'1': VDD voltage above lower limit                                                                                                                                                   |
| STATUS0 | 0    | r    | 0': over voltage at VDD<br>'1': VDD voltage below upper limit                                                                                                                                                     |

## 9.2.7 Contents of the SPI registers after a reset condition

Note: The registers for device identifier and revision (ID\_REG and REV\_REG) are not affected by reset.

### DIA\_REG

|          | 7       | 6  | 5       | 4      | 3     | 2     | 1     | 0     |
|----------|---------|----|---------|--------|-------|-------|-------|-------|
|          | ABE/DIS | OT | CurrRed | CurLim | DIA21 | DIA20 | DIA11 | DIA10 |
| POR      | x       | 1  | 1       | 1      | 1     | 1     | 1     | 1     |
| SPIR     | x       | 1  | 1       | 1      | 1     | 1     | 1     | 1     |
| ABE/DISR | x       | 1  | 1       | 1      | 1     | 1     | 1     | 1     |
| RDR      | x       | 1  | 1       | 1      | x     | x     | x     | x     |
| DIACLR1  | x       | x  | x       | x      | x     | x     | 1     | 1     |
| DIACLR2  | x       | x  | x       | x      | 1     | 1     | x     | x     |

### CONFIG\_REG

|        | 7    | 6   | 5    | 4    | 3   | 2   | 1     | 0  |
|--------|------|-----|------|------|-----|-----|-------|----|
|        | MODE | MUX | SIN1 | SIN2 | CL1 | CL2 | RESET | SL |
| POR    | 1    | 1   | 1    | 1    | 1   | 0   | 1     | 0  |
| SPIR   | 1    | 1   | 1    | 1    | 1   | 0   | 1     | 0  |
| DISR   | x    | 1   | 1    | 1    | x   | x   | 1     | x  |
| SFMODE | 1    | 1   | 1    | 1    | 1   | 0   | 1     | 0  |

### STATCON\_REG

|        | 7       | 6       | 5       | 4       | 3       | 2       | 1       | 0       |
|--------|---------|---------|---------|---------|---------|---------|---------|---------|
|        | CONFIG2 | CONFIG1 | CONFIG0 | DIACLR2 | DIACLR1 | STATUS2 | STATUS1 | STATUS0 |
| POR    | 1       | 1       | 0       | 1       | 1       | x       | x       | x       |
| SPIR   | 1       | 1       | 0       | 1       | 1       | x       | x       | x       |
| SFMODE | 1       | 1       | 0       | 1       | 1       | x       | x       | x       |

POR: Reset due to VDD power up

SPIR: Reset via SPI by writing 0 into the RESET of CONFIG\_REG

ABE/DISR: Reset due to enabling or disabling the power stages via DIS or ABE (edge triggered)

DISR: Reset due to a disabled power stage by DIS or ABE (level triggered)

RDR: Reset due to a read access to DIA\_REG

DIACLR1: Reset via SPI by writing 0 into the DIACLR1 of STATCON\_REG

DIACLR2: Reset via SPI by writing 0 into the DIACLR2 of STATCON\_REG

SFMODE: Reset by setting the TLE8209-2SA into the Status Flag Mode (VDDIO = 0V)

x: No change

Note: If a reset condition is not listed for a particular register it has no effect on the contents of this register.

### 9.3 Electrical Characteristics SPI

#### Electrical Characteristics: SPI Interface

$V_S = 5\text{ V to } 28\text{ V}$ ;  $V_{DD} = 5.0\text{ V}$ ;  $V_{DDIO} = 2.9\text{ V to } 5.5\text{ V}$ ,  $T_j = -40\text{ }^\circ\text{C to } 150\text{ }^\circ\text{C}$ , all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

| Pos.                                     | Parameter                                                                                                                                                                                                                                                                                                    | Symbol            | Limit Values |        |            | Unit | Test Conditions                                                                             |
|------------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------------|--------------|--------|------------|------|---------------------------------------------------------------------------------------------|
|                                          |                                                                                                                                                                                                                                                                                                              |                   | Min.         | Typ.   | Max.       |      |                                                                                             |
| SPI-Timing (see Figure 17) <sup>1)</sup> |                                                                                                                                                                                                                                                                                                              |                   |              |        |            |      |                                                                                             |
| 9.3.1                                    | Cycle-time (1)                                                                                                                                                                                                                                                                                               | $t_{\text{cyc}}$  | 490          | —      | —          | ns   | referred to master                                                                          |
| 9.3.2                                    | Enable Lead Time (2)                                                                                                                                                                                                                                                                                         | $t_{\text{lead}}$ | 50           | —      | —          | ns   | referred to master                                                                          |
| 9.3.3                                    | Enable Lag Time (3)                                                                                                                                                                                                                                                                                          | $t_{\text{lag}}$  | 150          | —      | —          | ns   | referred to master                                                                          |
| 9.3.4                                    | Data Valid (4)<br>H->L: $V_{\text{SCK}}=2\text{V} \rightarrow V_{\text{SO}}=0.2 V_{\text{DDIO}}$<br>L->H: $V_{\text{SCK}}=2\text{V} \rightarrow V_{\text{SO}}=0.8 V_{\text{DDIO}}$<br>if $V_{\text{DDIO}} < 4.5\text{V}$ :<br>L->H: $V_{\text{SCK}}=2\text{V} \rightarrow V_{\text{SO}}=0.7 V_{\text{DDIO}}$ | $t_{\text{v}}$    | —<br>—       | —<br>— | 150<br>230 | ns   | $C_{\text{L}} = 200 \text{ pF}$<br>$C_{\text{L}} = 350 \text{ pF}$<br>referred to TLE8209-2 |
| 9.3.5                                    | Data Setup Time (5)                                                                                                                                                                                                                                                                                          | $t_{\text{su}}$   | 40           | —      | —          | ns   | referred to master                                                                          |
| 9.3.6                                    | Data Hold Time (6)                                                                                                                                                                                                                                                                                           | $t_{\text{h}}$    | 40           | —      | —          | ns   | referred to master                                                                          |
| 9.3.7                                    | Disable Time (7)                                                                                                                                                                                                                                                                                             | $t_{\text{dis}}$  | —            | —      | 100        | ns   | referred to TLE8209-2                                                                       |
| 9.3.8                                    | Transfer Delay (8)                                                                                                                                                                                                                                                                                           | $t_{\text{dt}}$   | 250          | —      | —          | ns   | referred to master                                                                          |
| 9.3.9                                    | Disable Lead Time (9)                                                                                                                                                                                                                                                                                        | $t_{\text{dld}}$  | 250          | —      | —          | ns   | referred to master                                                                          |
| 9.3.10                                   | Disable Lag Time (10)                                                                                                                                                                                                                                                                                        | $t_{\text{dlg}}$  | 250          | —      | —          | ns   | referred to master                                                                          |
| 9.3.11                                   | Access time (11)                                                                                                                                                                                                                                                                                             | $t_{\text{acc}}$  | 8.35         | —      | —          | μs   | referred to master                                                                          |

1) All timing parameters specified by design - not subject to production test

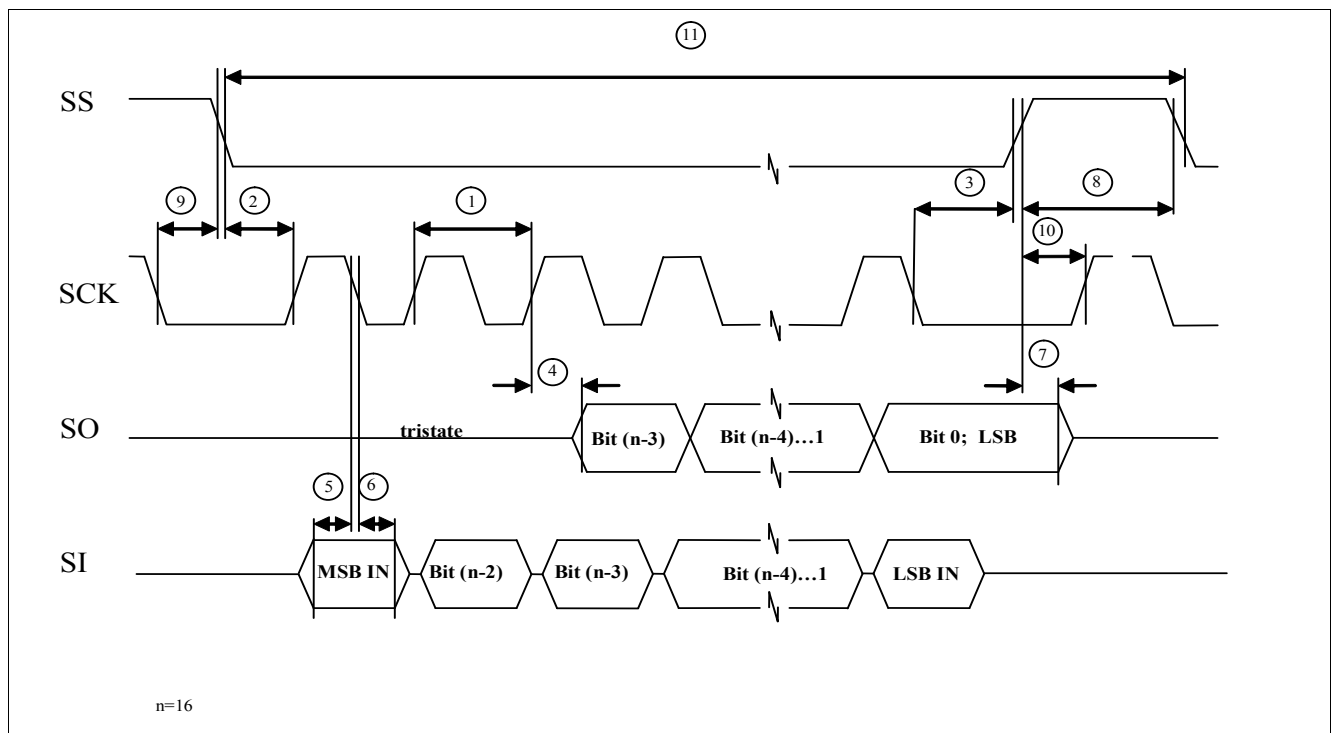
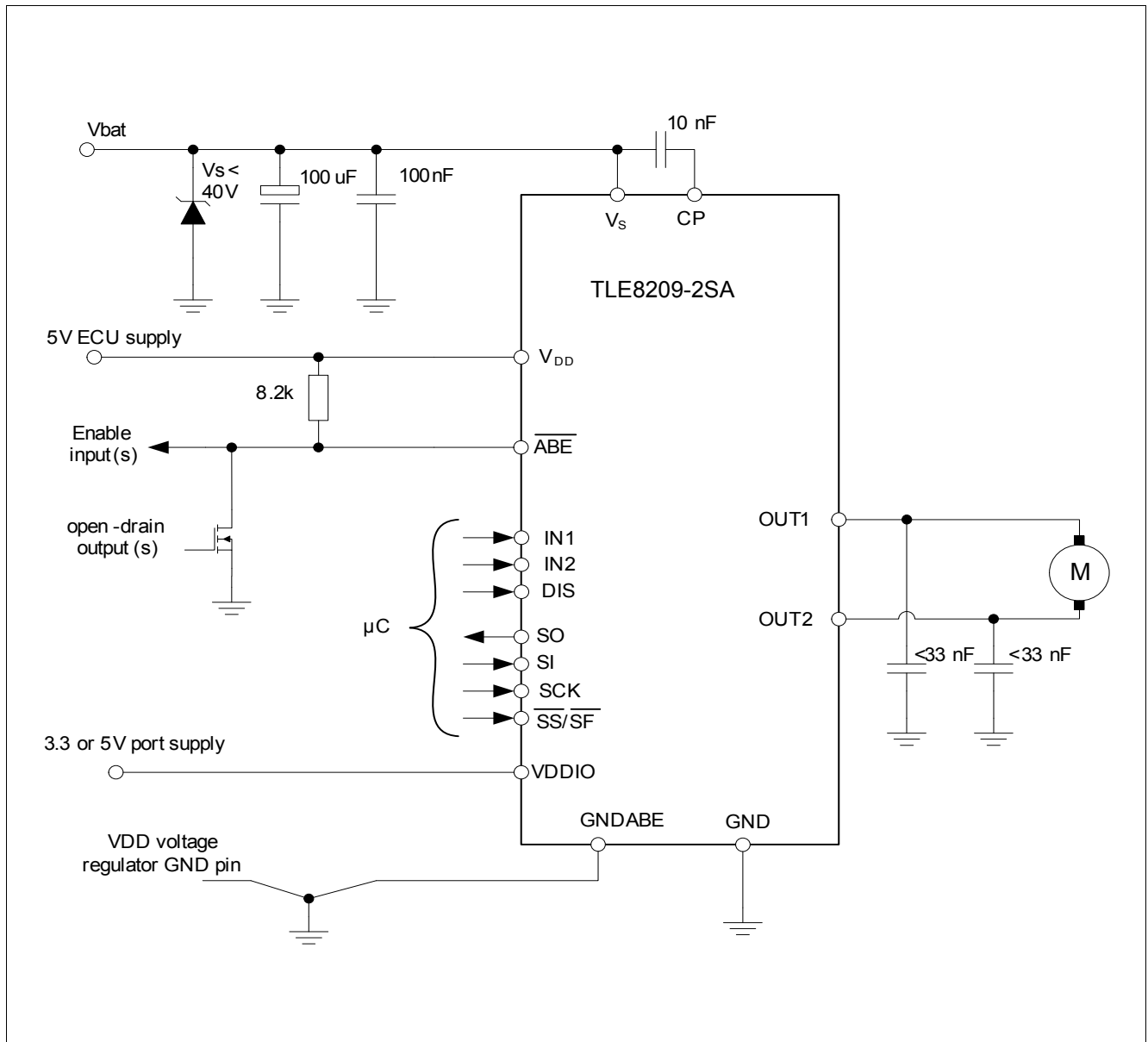


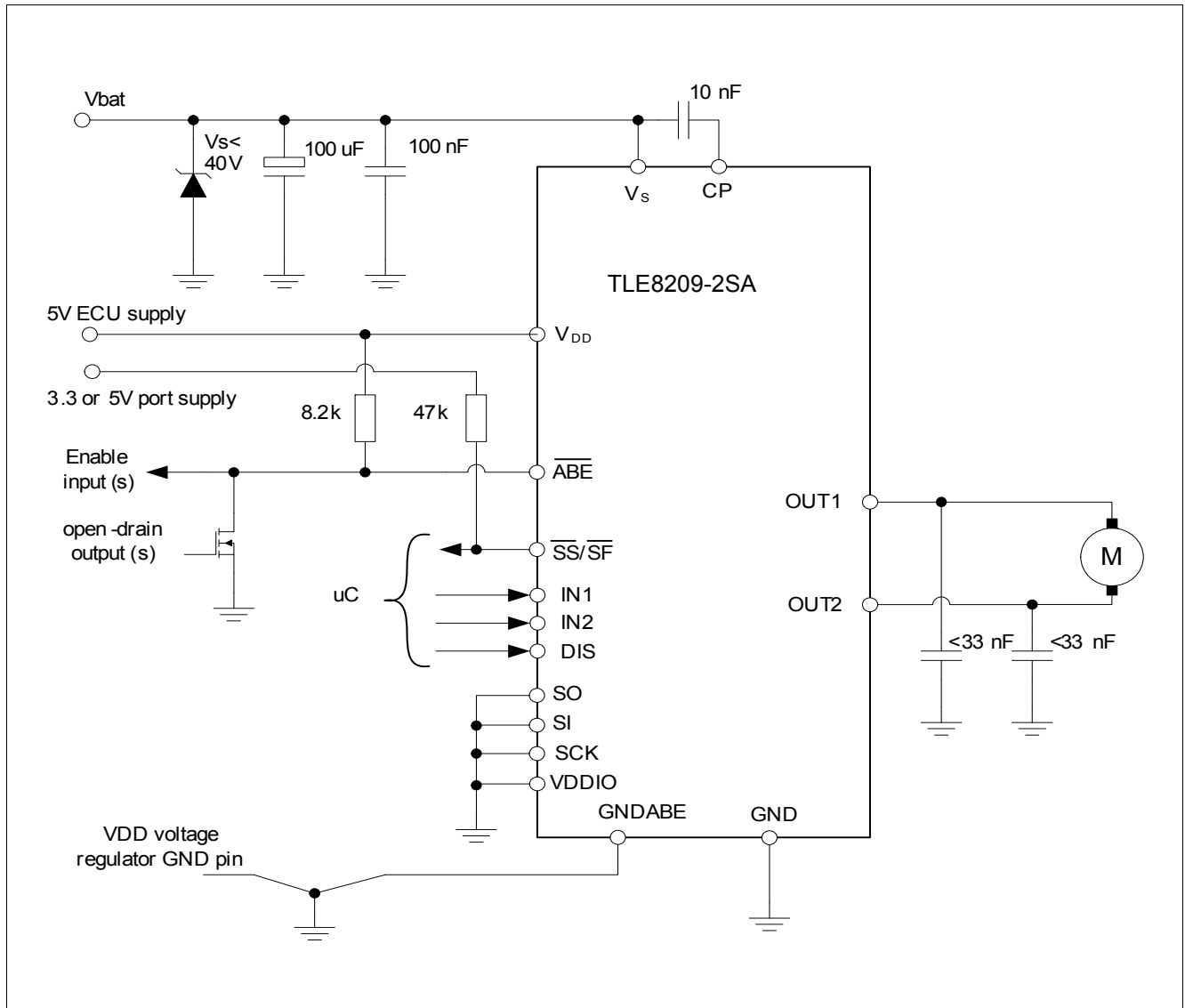
Figure 17 SPI Timing

## 10 Application Information

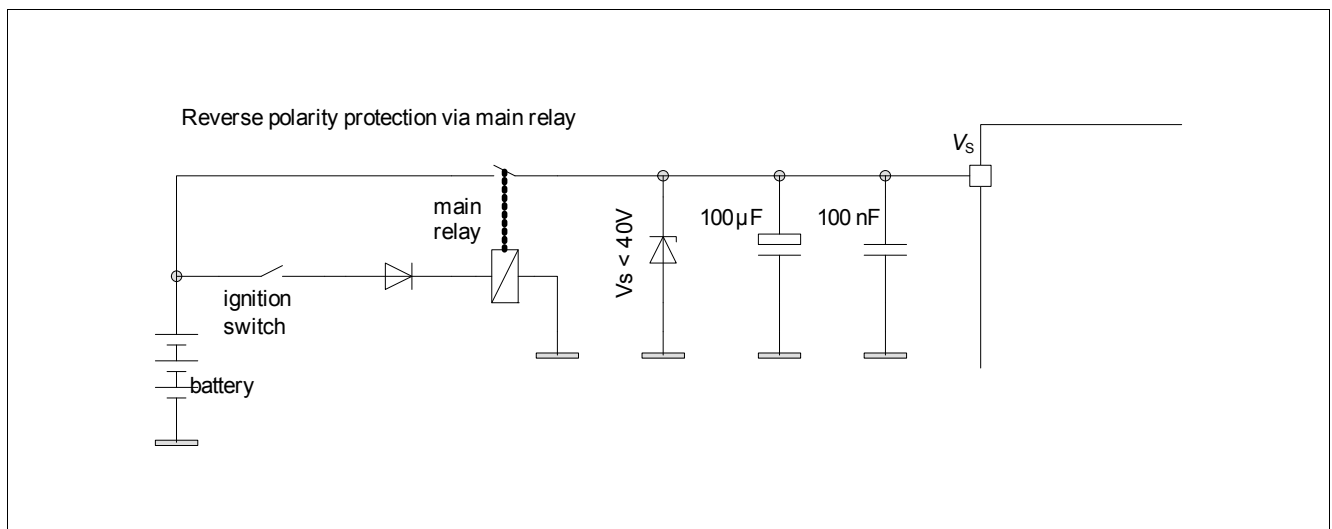
*Note: The following simplified application examples are given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device. The function of the described circuits must be verified in the real application*



**Figure 18 Application Example H-Bridge with SPI-Interface**

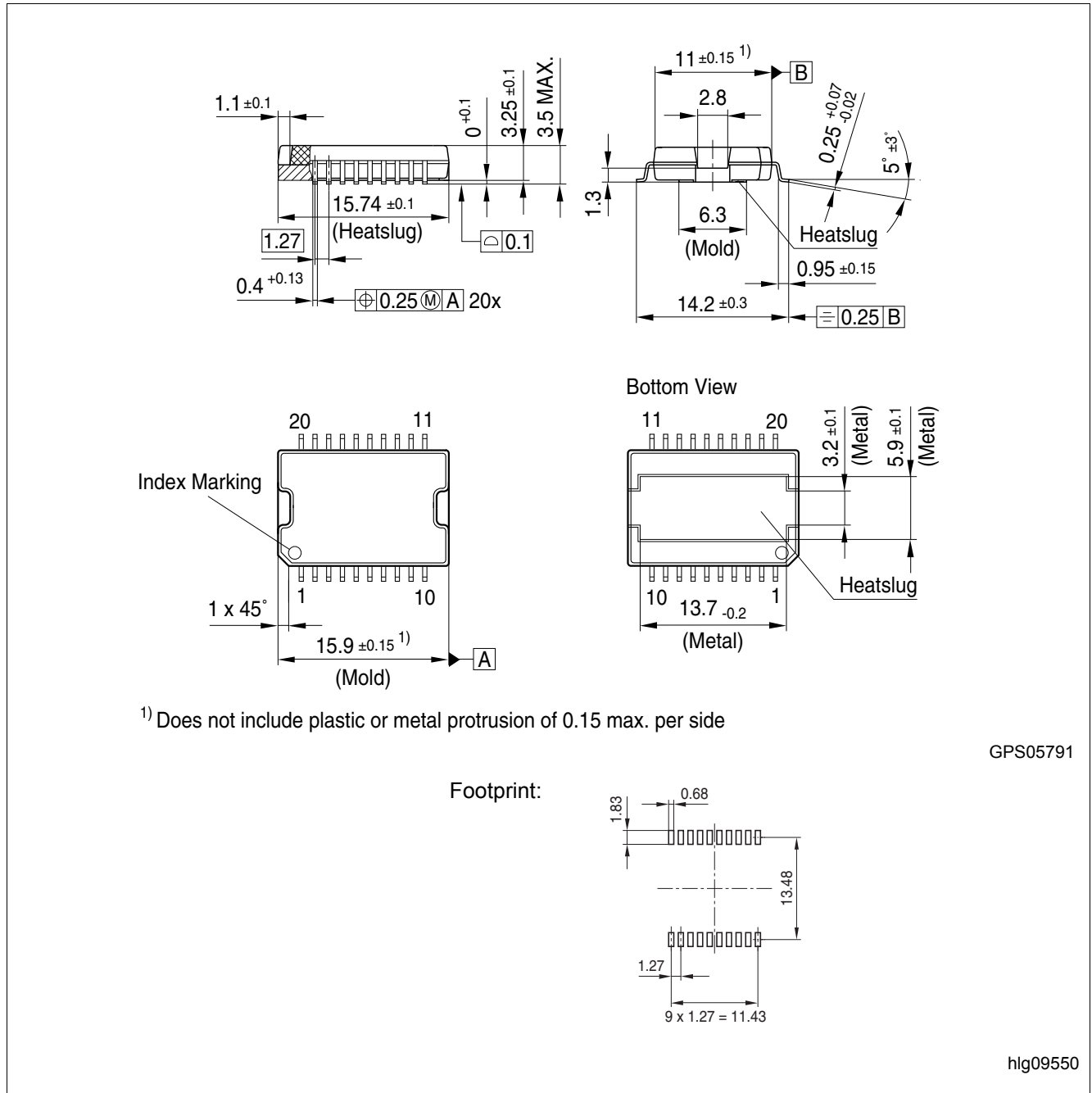


**Figure 19** Application Example with Status Flag



**Figure 20** Application Examples for Overvoltage and Reverse-Voltage Protection

# 11 Package Outlines TLE8209-2SA



**Figure 21 PG-DSO-20-65** (Plastic Dual Small Outline Package)

## Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e. Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

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Dimensions in mm

## 12 Revision History

| Revision | Date       | Comments / Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
|----------|------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 0.1      | 2008-08-21 | Initial Product Proposal                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
| 0.2      | 2008-12-05 | <ul style="list-style-type: none"> <li>- General: Package PG-DSO-20-37 (TLE8209-2SA) added</li> <li>- Page 13, Chapter 6: Description of digital inputs modified</li> <li>- Page 14, Pos. 6.0.36 &amp; 6.0.37: typ. values removed</li> <li>- Page 16: Switching times adjusted to TLE8209-1 values</li> <li>- Page 36ff: Application diagrams updated (Figures 19 &amp; 20)</li> <li>- Page 38: Package drawing added</li> <li>- Page 39: Package drawing updated</li> </ul>                                                               |
| 0.3      | 2009-07-31 | Target Data Sheet <ul style="list-style-type: none"> <li>- General: Package names changed</li> <li>- Page 24, Pos. 8.10.5, current limit hysteresis min. changed</li> </ul>                                                                                                                                                                                                                                                                                                                                                                 |
| 0.4      | 2009-12-11 | Preliminary Data Sheet <ul style="list-style-type: none"> <li>- Limits revised throughout the whole document</li> <li>- Cover: Subtitle changed to "SPI Programmable H-Bridge"</li> <li>- Page 3: Feature List and Functional Description revised</li> <li>- Page 17ff: Rearranged figures 6 to 9</li> <li>- Page 20: Figures 11 &amp; 12 revised</li> <li>- Page 21: Short circuit description revised</li> <li>- Page 36: Application Diagram with Status Flag (Figure 20) updated</li> <li>- Page 38: Package Drawing updated</li> </ul> |
| 1.0      | 2010-02-16 | Data Sheet <ul style="list-style-type: none"> <li>- General: Single package version: PG-DSO-20-65 (PowerSO20) only.</li> <li>- Page 3, Overview: added "low standby current" in feature list</li> <li>- Page 11, Pos. 5.4.1: Parameter name changed to "Supply Current";</li> <li>- Page 11, Pos. 5.4.1: added limits for <math>I_{VS}</math> at <math>V_{DD} = 0V</math>.</li> <li>- Page 19, Figure 11 updated.</li> </ul>                                                                                                                |
| 1.2      | 2012-12-20 | <ul style="list-style-type: none"> <li>- Page 3: Feature list revised</li> <li>- Page 22, Pos. 8.10.4: <math> I_{L4} </math> max. changed from 10.5A to 10.0A</li> <li>- Page 27, Chapter 9.2.3: Description of device identifier and revision modified</li> </ul>                                                                                                                                                                                                                                                                          |

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